

PCTEST ENGINEERING LABORATORY, INC.

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HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea Date of Testing: 02/25/2019 - 02/28/2019 Test Site/Location: PCTEST Lab, Columbia, MD, USA Test Report Serial No.: 1M1901100003-20-R2.A3L Date of Issue:

FCC ID: A3LSMG977U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing

Application Type: Certification
FCC Rule Part(s): CFR §20.19(b)
HAC Standard: ANSI C63.19-2011

CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017

285076 D01 HAC Guidance v05

285076 D02 T-Coil testing for CMRS IP v03

03/27/2019

DUT Type: Portable Handset **Model:** SM-G977U

Test Device Serial No.: Pre-Production Sample [S/N: 1278B]

C63.19-2011 HAC Category: M4 (RF EMISSIONS CATEGORY)

Note: This revised Test Report (S/N: 1M1901100003-20-R2.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.









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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-86581 to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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2. **DUT DESCRIPTION**



FCC ID: A3LSMG977U

Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Model: SM-G977U Serial Number: 1278B

Antenna Configurations: Internal Antenna Portable Handset DUT Type:

Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for all WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.

II. LTE Band Selection

This device supports the following pairs of LTE bands with similar frequencies: LTE B4 & B66 as well as B38 & B41. Each pair of LTE bands has the same target power and shares the same transmission path. Since the supported frequency spans for the smaller LTE bands are completely covered by the larger LTE bands, only the larger LTE bands (LTE B66 and B41) were evaluated for hearing-aid compliance.

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Table 2-1 SM-G977U HAC Air Interfaces

			00770	HAC Air interfaces	
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service
	835	V0	Vaa	Voca MIEL on DT	CMDC Vains
CDMA	1900	VO	Yes	Yes: WIFI or BT	CMRS Voice
	EvDO	VD	No ¹	Yes: WIFI or BT	Google Duo
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice
GSM	1900	VO	res	tes. WIFI OF BT	CIVIRS VOICE
	GPRS/EDGE	VD	No ¹	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No ¹	Yes: WIFI or BT	CMRS Voice
UIVITS	1900				
	HSPA	VD	No ¹	Yes: WIFI or BT	Google Duo
	700 (B12)	VD	No ¹	Yes: WIFI or BT	VoLTE, Google Duo
	780 (B13)				
	790 (B14)				
	850 (B5)				
LTE (FDD)	850 (B26)				
LIE (FDD)	1700 (B4)		NO.		
	1700 (B66)				
	1900 (B2)				
	2300 (B30)				
	2500 (B7)				
	2600 (B38)				
LTE (TDD)	2600 (B41)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo
	3600 (B48)				
NR	28000 (Band n261)	VD	No ²	Yes: WIFI or BT	Google Duo
	2450				
	5200 (U-NII 1)				
WIFI	5300 (U-NII 2A)	VD	No ¹	Yes: CDMA, GSM, UMTS, LTE, or NR	VoWIFI, Google Duo
	5500 (U-NII 2C)				
	5800 (U-NII 3)				
ВТ	2450	DT	No	Yes: CDMA, GSM, UMTS, LTE, or NR	N/A
Type Transport			Notes:	or MIF and low-nower exemption	

VO = Voice Only

= Voice Only

DT = Digital Data - Not intended for Voice Services VD = CMRS and/or IP Voice over Data Transport 1. Evaluated for MIF and low-power exemption.

2. n261 is currently outside the scope of ANSI C63.19 and FCC HAC regulations therefore it was not evaluated.

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ANSI/IEEE C63.19 PERFORMANCE CATEGORIES 3.

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters		
Near field Category	E-field emissions CW dB(V/m)		
	f < 960 MHz		
M1	50 to 55		
M2	45 to 50		
M3	40 to 45		
M4	< 40		
	f > 960 MHz		
M1	40 to 45		
M2	35 to 40		
M3	30 to 35		
M4	< 30		
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011			

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4. SYSTEM SPECIFICATIONS

EF3DV3 E-Field Probe Description

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 30 MHz to 6.0 GHz

(absolute accuracy ±5.1%, k=2)

Frequency: 30 MHz to > 6 GHz;

Linearity: ± 0.2 dB (30 MHz to 6 GHz)

Directivity $\pm 0.2 \text{ dB}$ in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 337 mm (Tip: 20 mm)

Tip diameter: 4.0 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 1.5 mm



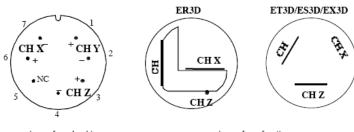
Figure 4-1E-field Free-space
Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement").

Connector Plan



(seen from back) (seen from front)

The antistatic shielding inside the probe is connected to the probe connector case.

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Instrumentation Chain

Equation 1

Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

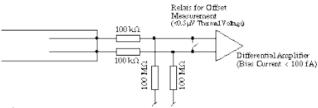
whereby

Eı: electric field in V/m

voltage of channel i at the connector in µV Uí. sensitivity of channel i in µV/(V/m)2 Norm: ConvF: enhancement factor in liquid (ConvF=1 for Air) DCP: diode compression point in µV

CF. signal crest factor (peak power/average power)

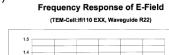
Conditions of Calibration



- a lower input impedance of the amplifier will result in different sensitivity factors Norm; and DCP
- larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).



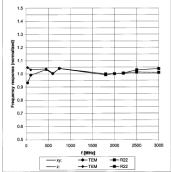


Figure 4-2 E-Field Probe Frequency Response

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SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 4-3 SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

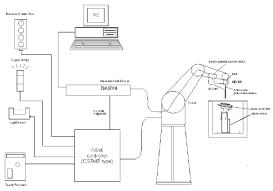


Figure 4-4SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ U_i &= \text{input signal of channel i} & (i = x, y, z) \\ cf &= \text{crest factor of exciting field} & (\text{DASY parameter}) \\ dcp_i &= \text{diode compression point} & (\text{DASY parameter}) \end{aligned}$$

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From the compensated input signals the primary field data for each channel can be evaluated:

$$\mathbf{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with V_i = compensated signal of channel i (i = x, y, z) $Norm_i$ = sensor sensitivity of channel i (i = x, y, z)

 $\mu V/(V/m)^2$ for E-field Probes

ConvF = sensitivity enhancement in solution

 E_i = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

Environmental Conditions

Environmental conditions such as temperature and relative humidity are monitored to ensure there are no impacts on system specifications. Proper voltage and power line frequency conditions are maintained with three phase power sources. Environmental noise and reflections are monitored through system checks.

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TEST PROCEDURE 5.

RF EMISSIONS

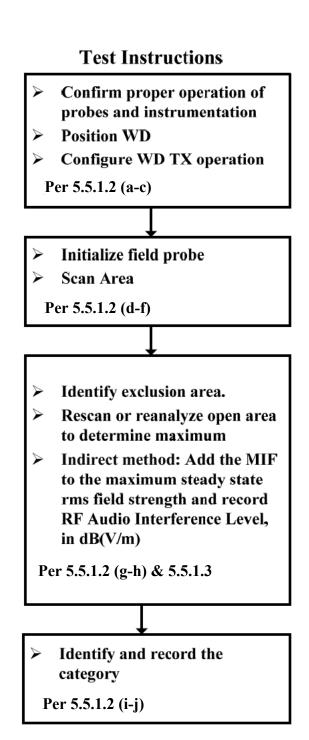


Figure 5-1 RF Emissions Flow Chart

	_			
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Test Setup

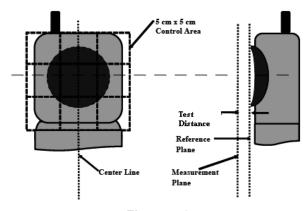


Figure 5-2 E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

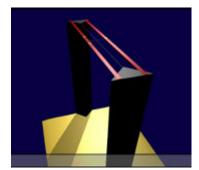


Figure 5-3 **HAC Phantom**

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

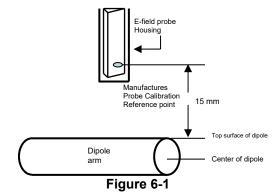
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6. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

Measurement of CW

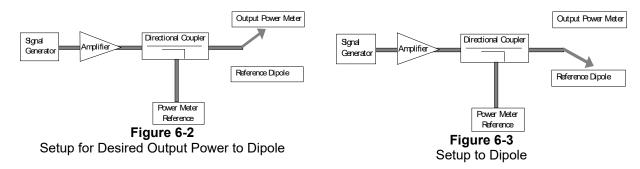
Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

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REV 3.3.M

RF power was recorded using both an average and a peak power reading meter.



Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis

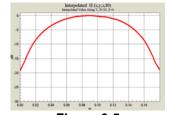
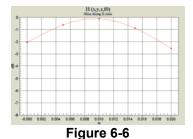
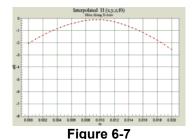


Figure 6-5
2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

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III. System Check Results

Validation Results

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
2/25/2019	835	4035	1415	1082	20.0	109.0	110.9	-1.7%
2/25/2019	1880	4035	1415	1064	20.0	88.7	89.0	-0.3%
2/25/2019	2600	4035	1415	1013	20.0	86.8	84.5	2.7%
2/25/2019	3500	4035	1415	1005	20.0	86.6	84.1	2.9%

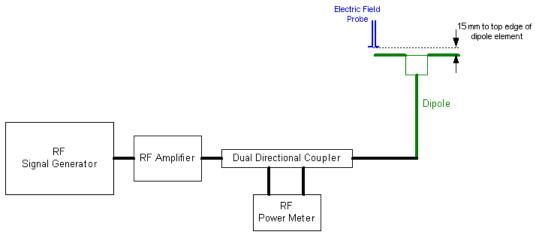


Figure 6-8 System Check Setup

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7. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- 5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

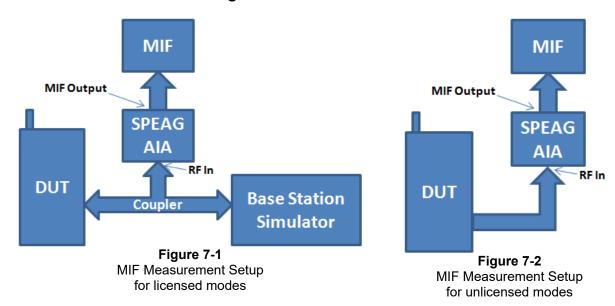
The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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II. MIF Measurement Block Diagrams



III. Measured Modulation Interference Factors:

Table 7-1 CDMA Modulation Interference Factors¹

Mode		Cell			PCS		
		1013	384	777	25	600	1175
	RC1/SO3	3.01	3.04	3.06	3.02	3.05	3.08
CDMA	RC1/SO55	-19.04	-19.21	-19.13	-19.19	-19.26	-19.83
	EvDO	-17.96	-18.84	-17.85	-18.08	-18.22	-19.67

Table 7-2 GSM Modulation Interference Factors¹

		GSM850			GSM1900		
Mc	ode	128	190	251	512	661	810
CCM	Voice	3.50	3.50	3.50	3.54	3.54	3.54
GSM	EDGE	3.76	3.77	3.72	3.72	3.74	3.70

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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Table 7-3 UMTS Modulation Interference Factors¹

M	ode	UMTS V			UMTS IV			UMTS II		
IVI	ode	4132	4183	4233	1312	1412	1513	9262	9400	9538
	12.2 kbps RMC	-23.47	-23.17	-23.26	-22.91	-23.14	-22.92	-22.90	-23.53	-23.19
UMTS	12.2 kbps AMR	-13.49	-13.39	-13.52	-14.02	-13.71	-13.64	-13.99	-13.54	-13.70
	HSUPA Subtest1	-23.61	-23.28	-23.30	-23.02	-23.64	-23.16	-23.21	-23.62	-23.45

Table 7-4 LTE EDD Modulation Interference Factors 1,2

	<u> </u>		ouulation	interrenc	e raciois	,	
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
12	707.5	23095	10	16QAM	1	0	-11.05
13	782.0	23230	10	16QAM	1	0	-10.43
14	793.0	23330	10	16QAM	1	0	-9.85
26	831.5	26865	15	16QAM	1	0	-10.39
5	836.5	20525	10	16QAM	1	0	-10.35
66	1745.0	132322	20	16QAM	1	0	-10.06
2	1880.0	18900	20	16QAM	1	0	-10.06
30	2310.0	27710	10	16QAM	1	0	-10.48
7	2535.0	21100	20	16QAM	1	0	-9.81
7	2535.0	21100	20	64QAM	1	0	-9.90
7	2535.0	21100	20	256QAM	1	0	-9.90
7	2535.0	21100	20	QPSK	1	0	-14.59
7	2535.0	21100	20	16QAM	1	50	-10.05
7	2535.0	21100	20	16QAM	1	99	-10.04
7	2535.0	21100	20	16QAM	50	0	-16.36
7	2535.0	21100	20	16QAM	100	0	-17.41
7	2535.0	21100	15	16QAM	1	0	-9.82
7	2535.0	21100	10	16QAM	1	0	-9.83
7	2535.0	21100	5	16QAM	1	0	-9.54
7	2502.5	20775	5	16QAM	1	0	-10.91
7	2567.5	21425	5	16QAM	1	0	-9.59

Table 7-5 LTE FDD Uplink Carrier Aggregation Modulation Interference Factor^{1,3}

						00	0								
				PCC				SCC							
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL) Channel	PCC (UL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL) Channel	SCC (UL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_5B	LTE B5	10	20525	836.5	16QAM	1	0	LTE B5	5	20453	829.3	16QAM	1	24	-9.40
CA_66B	LTE B66	10	132322	1745.0	16QAM	1	0	LTE B66	10	132223	1735.1	16QAM	1	49	-10.47
CA_66C	LTE B66	20	132322	1745.0	16QAM	1	0	LTE B66	20	132124	1725.2	16QAM	1	99	-10.62

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

³Note: LTE FDD ULCA was evaluated to ensure LTE FDD standalone was the worst-case scenario. The configurations in Table 7-5 were determined from Table 7-4 and satisfy the configuration requirements as defined in 3GPP 36.101.

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² Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

Table 7-6 LTE TDD B41 Power Class 3 Modulation Interference Factors^{1,2}

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	1.50
41	2593.0	40620	20	QPSK	1	0	1.44
41	2593.0	40620	20	64QAM	1	0	1.49
41	2593.0	40620	20	256QAM	1	0	1.49
41	2593.0	40620	20	16QAM	1	50	1.49
41	2593.0	40620	20	16QAM	1	99	1.48
41	2593.0	40620	20	16QAM	50	0	1.36
41	2593.0	40620	20	16QAM	100	0	1.36
41	2593.0	40620	15	16QAM	1	0	1.53
41	2593.0	40620	10	16QAM	1	0	1.52
41	2593.0	40620	5	16QAM	1	0	1.45
41	2506.0	39750	15	16QAM	1	0	1.39
41	2549.5	40185	15	16QAM	1	0	1.37
41	2636.5	41055	15	16QAM	1	0	1.48
41	2680.0	41490	15	16QAM	1	0	1.43

Table 7-7 LTE TDD B48 Modulation Interference Factors^{1,3}

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
48	3603.3	55773	20	16QAM	1	0	-2.51
48	3603.3	55773	20	QPSK	1	0	-2.54
48	3603.3	55773	20	64QAM	1	0	-2.39
48	3603.3	55773	20	256QAM	1	0	-2.44
48	3603.3	55773	20	16QAM	1	50	-2.39
48	3603.3	55773	20	16QAM	1	99	-2.38
48	3603.3	55773	20	16QAM	50	0	-2.58
48	3603.3	55773	20	16QAM	100	0	-2.59
48	3602.5	55765	15	64QAM	1	74	-2.34
48	3601.7	55757	10	64QAM	1	49	-2.35
48	3600.8	55748	5	64QAM	1	24	-2.37
48	3557.5	55315	15	64QAM	1	74	-2.41
48	3647.5	56215	15	64QAM	1	74	-2.62
48	3692.5	56665	15	64QAM	1	74	-2.34

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

³ Note: LTE TDD B48 MIFs were taken using UL-DL Configuration 6. More information about the chosen UL-DL Configuration can be found in Section 10.

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²Note: LTE TDD B41 MIFs were taken using UL-DL Configuration 2. More information about the chosen UL-DL Configuration can be found in Section 10.

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Table 7-8 802.11b (2.4GHz, SISO) Modulation Interference Factors^{1,2}

-7.42

-6.42

אכ	12. I ID (2.40	JNZ, SISU) iviodulatioi	imteneren	ce ractors	.,_
		802.1	1b MIF Mea	surements	s [dB]	
	Mode		Data Rat	e [Mbps]		
		1	2	5.5	11	

-9.16

Table 7-9 802.11g (2.4GHz, SISO) Modulation Interference Factors^{1,2}

-9.75

802.11b

		802.11g MIF Measurements [dB]							
Mode		Data Rate [Mbps]							
	6	6 9 12 18 24 36 48 54							
802.11g	-7.50	-6.72	-6.17	-5.43	-5.02	-4.75	-4.84	-4.89	

Table 7-10 802.11g (2.4GHz, MIMO) Modulation Interference Factors^{1,2}

		802.11g MIF Measurements [dB]									
Mode		Data Rate [Mbps]									
	12	12 18 24 36 48 72 92 108									
802.11g	-7.37	-6.73	-6.10	-5.41	-4.84	-4.72	-4.84	-4.94			

Table 7-11 802.11n (2.4GHz, SISO) Modulation Interference Factors^{1,2}

		802.11n (2.4GHz) MIF Measurements [dB]								
Mode		Data Rate [Mbps]								
	6.5	6.5 13 19.5 26 39 52 58.5 65								
802.11n	-7.26	-7.26 -6.02 -5.38 -5.00 -4.76 -4.82 -4.93 -5.03								

Table 7-12 802 11n (2 4GHz MIMO) Modulation Interference Factors^{1,2}

	002	2.1111 (2.40	riz, ivilivio	iviodulatio	ii iiileiieiei	ice i actors), · · ·				
	802.11n (2.4GHz) MIF Measurements [dB]										
Mode	Data Rate [Mbps]										
	13	26	39	52	78	104	117	130			
802.11n	-7.33	-6.01	-5.35	-5.00	-4.71	-4.77	-4.84	-4.96			

Table 7-13 802 11ax (2 4GHz SU SISO) Modulation Interference Factors^{1,2}

		00Z.11a	X (2.40112	<u>., 30, 313</u>	o) wodu	alion inte	ICICIICE I	aciois				
			20MI	Hz 802.11a	x (2.4GHz) MIF Meas	urements	[dB]				
Mode		Data Rate [Mbps]										
	4	10	24	33	49	65	73	81	98	108		
802.11ax	-6.99	-5.79	-5.17	-4.87	-4.71	-4.83	-4.92	-5.00	-5.09	-5.28		

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-14 802.11ax (2.4GHz, SU, MIMO) Modulation Interference Factors^{1,2}

			20MI	Hz 802.11a	x (2.4GHz) MIF Meas	urements	[dB]				
Mode		Data Rate [Mbps]										
	8	32	48	66	98	130	146	162	196	216		
802.11ax	-5.73 -4.83 -4.67 -4.78 -5.03 -5.29 -5.35 -5.57 -5.63 -5.73											

Table 7-15

802.11a (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

		•	802.11	la MIF Mea	surements	[dB]				
Mode Data Rate [Mbps]										
	6	9	12	18	24	36	48	54		
802.11a	-7.51 -6.80 -6.26 -5.55 -5.10 -4.78 -4.93 -4.96									

Table 7-16

802.11a (5GHz, 20MHz BW, MIMO) Modulation Interference Factors^{1,2}

			surements	[dB]								
Mode		Data Rate [Mbps]										
	12	18	24	36	48	72	92	108				
802.11a	-7.46 -6.78 -6.19 -5.49 -5.11 -4.77 -4.89 -4.99											

Table 7-17

802.11n (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

		20MH	z BW 802.	11n (5GHz) MIF Mea	surements	[dB]					
Mode		Data Rate [Mbps]										
	6.5	13	19.5	26	39	52	58.5	65				
802.11n	-7.48 -6.19 -5.48 -5.01 -4.85 -4.89 -5.00 - -											

Table 7-18

802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors^{1,2}

		20MH	z BW 802.	11n (5GHz) MIF Meas	surements	[dB]					
Mode		Data Rate [Mbps]										
	13	26	39	52	78	104	117	130				
802.11n	-7.35 -6.09 -5.43 -4.99 -4.74 -4.80 -4.90 -5.0											

Table 7-19

802.11ac (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

		20MHz BW 802.11ac (5GHz) MIF Measurements [dB]										
Mode		Data Rate [Mbps]										
	6.5	13	19.5	26	39	52	58.5	65	78			
802.11ac	c -7.45 -6.24 -5.48 -5.03 -4.84 -4.87 -4.97 -5.07 -5.25											

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-20 802.11ac (5GHz, 20MHz BW, MIMO) Modulation Interference Factors^{1,2}

		2	OMHz BW	802.11ac	(5GHz) MIF	Measurer	ments [dB]					
Mode		Data Rate [Mbps]										
	13	26	39	52	78	104	117	130	156			
802.11ac	-6.09	-5.01	-4.71	-4.74	-5.13	-5.53	-5.64	- 5.79	-6.06			

Table 7-21

802.11ax (5GHz, 20MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

	COZ. 1 Tax (COTIZ, ZOTTI Z DVI, CO, CICO) Michaelori Interior Cico i detero											
	20MHz 802.11ax (5GHz) MIF Measurements											
Mode		Data Rate [Mbps]										
	4	16	24	33	49	65	73	81	98	108	122	135
802.11ax	ax -7.04 -5.86 -5.23 -4.94 -4.79 -4.88 -4.99 -5.10 -5.24 -5.37 -5.42 -5.61											

Table 7-22

802.11ax (5GHz, 20MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

	COLITION (COLL) LOWIN LE DIV, CO, MINIO / MODULATION MICHIGATION													
	20MHz 802.11ax (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]												
	8	32	48	66	98	130	146	162	196	216	244	270		
802.11ax	-5.77	-5.77 -4.91 -4.79 -4.90 -5.19 -5.51 -5.57 -5.71 -5.79 -5.89 -5.96 -6.14												

Table 7-23

802.11n (5GHz. 40MHz BW, SISO) Modulation Interference Factors^{1,2}

662.1 III (CGF12, TOWN 12 BW, GIGG) Woodalation Interference Latere														
		40MH	z BW 802.	11n (5GHz) MIF Meas	surements	[dB]							
Mode		Data Rate [Mbps]												
	13.5	27	40.5	54	81	108	121.5	135						
802.11n	-5.97	-5.97 -4.91 -4.59 -4.80 -5.26 -5.74 -5.90 -6.06												

Table 7-24

802.11n (5GHz, 40MHz BW, MIMO) Modulation Interference Factors^{1,2}

	COZ.THY (COTIZ, TOWN IZ BYY, MINYO) WOODING THEORY OF ACCORD													
		40MH	z BW 802.	11n (5GHz	z) MIF Meas	surements	[dB]							
Mode		Data Rate [Mbps]												
	27	54	81	108	162	216	243	270						
802.11n	-5.84													

Table 7-25

802.11ac (5GHz, 40MHz BW, SISO) Modulation Interference Factors^{1,2}

		40MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]													
	13.5	27	40.5	54	81	108	121.5	135	180						
802.11ac	-5.97	-5.97 -4.92 -4.63 -4.76 -5.20 -5.67 -5.82 -5.98 -6.45													

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WIFI MIF values were found to be independent of the transmit channel.

Table 7-26802.11ac (5GHz, 40MHz BW, MIMO) Modulation Interference Factors^{1,2}

		40MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]													
	27	54	81	108	162	216	243	270	360						
802.11ac	-4.80														

Table 7-27

802.11ax (5GHz, 40MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

ODE. Track (OOTIE, TOWNIE BYT, OO, OTOO) Woodington Witchford Colors														
	40MHz 802.11ax (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]												
	8	33	49	65	98	130	146	163	195	217	244	271		
802.11ax	-5.70	-5.70 -4.77 -4.64 -4.76 -5.10 -5.49 -5.55 -5.76 -5.84 -5.96 -6.08 -6.24												

Table 7-28

802.11ax (5GHz, 40MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

	COZ. I Tax (CCT IZ, +OWI IZ BVV, CC, WIIWC) Woodilation interior crock i dotoro														
		40MHz 802.11ax (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]													
	16	66	98	130	196	260	292	326	390	434	488	542			
802.11ax	-4.76	-4.76 -4.79 -5.13 -5.45 -5.75 -6.09 -6.19 -6.21 -6.44 -6.46 -6.47 -6.45													

Table 7-29

802.11ac (5GHz, 80MHz BW, SISO) Modulation Interference Factors^{1,2}

	80MHz BW 802.11ac (5GHz) MIF Measurements [dB]														
Mode		Data Rate [Mbps]													
	29.3	58.5	87.8	117	175.5	234	263.3	292.5	351	390					
802.11ac	-4.91	-4.91 -4.80 -5.31 -5.70 -6.26 -6.67 -6.78 -6.94 -7.06 -7.21													

Table 7-30

802.11ac (5GHz, 80MHz BW, MIMO) Modulation Interference Factors^{1,2}

602. Frac (3GF12, 80WH2 BW, WHWO) WOULD HITE HERE FACIOIS															
		80MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		Data Rate [Mbps]													
	58.5	117	175.5	234	351	468	526.5	585	702	780					
802.11ac	-4.72 -5.59 -6.07 -6.46 -6.94 -7.24 -7.24 -7.37 -7.39 -7.55														

Table 7-31

802.11ax (5GHz, 80MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

		OUZ. I TAX (SOLIZ, GOIVILIZ BW, GO, GIGO) Modulation interference i actors												
	80MHz 802.11ax (5GHz) MIF Measurements [dB]													
Mode	Data Rate [Mbps] 17 68 102 136 204 272 306 340 408 453 510 567													
802.11ax	-4.75 -4.81 -5.13 -5.52 -5.85 -6.24 -6.22 -6.32 -6.45 -6.44 -6.57 -6.60													

Table 7-32

802.11ax (5GHz, 80MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

		02. I TUX	(00112,	OOIVII IZ I	544, 00,	, ivillivio j	Modulat		ICICITOC	i doloio			
				80N	/Hz 802.11	ax (5GHz)	MIF Measu	ırements [dB]				
Mode	Data Rate [Mbps]												
	34	136	204	272	408	544	612	680	816	906	1020	1134	
802.11ax	-4.79	-4.79 -5.48 -5.82 -6.08 -6.28 -6.60 -6.56 -6.56 -6.77 -6.79 -6.76 -6.76											

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-33 802.11ax (2.4GHz, RU, SISO) Modulation Interference Factors^{1,2}

		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 49Mbps)								
	0	0 8 37 40 53 54 61								
802.11ax	-8.01	-7.96	-6.67	-6.66	-5.39	-5.40	-4.69			

Table 7-34

802.11ax (2.4GHz, RU, MIMO) Modulation Interference Factors^{1,2}

	,	20MHz 802.11ax (2.4GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 48Mbps)								
	0	0 8 37 40 53 54 61								
802.11ax	-7.86	-7.98	-6.57	-6.68	-5.37	-5.52	-4.67			

Table 7-35

802.11ax (5GHz, 20MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

		20MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 49Mbps)								
	0	0 8 37 40 53 54 61								
802.11ax	-7.90	-7.88	-6.69	-6.66	-5.45	-5.43	-4.74			

Table 7-36

802.11ax (5GHz, 20MHz BW, RU, MIMO) Modulation Interference Factors^{1,2}

	,	20MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 48Mbps)								
	0	8	37	40	53	54	61			
802.11ax	-7.86	-7.91	-6.69	-6.68	-5.50	-5.48	-4.75			

Table 7-37

802.11ax (5GHz, 40MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

		40MHz 802.11ax (5GHz) MIF Measurements [dB]							
Mode		RU Index (Data Rate: 49Mbps)							
	0	0 17 37 44 53 56 61 65							
802.11ax	-8.96	-8.96	-8.01	-7.99	-6.64	-6.58	-5.24	-4.63	

Table 7-38

802.11ax (5GHz, 40MHz BW, RU, MIMO) Modulation Interference Factors^{1,2}

	COZ: 1 Tax (CCT12, TOWN 12 BVV, TCC, WINVO) Wicadiation interference i actore									
		40MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 16Mbps)								
	0 17 37 44 53 56 61 65							65		
802.11ax	-9.28	-9.28	-8.68	-8.66	-7.32	-7.37	5.86	-4.84		

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-39802.11ax (5GHz, 80MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

		80MHz 802.11ax (5GHz) MIF Measurements [dB]									
Mode		RU Index (Data Rate: 17Mbps)									
	0	0 36 37 52 53 60 61 65 66 67							67		
802.11ax	-11.65	-11.49	-9.32	-9.11	-8.48	-8.43	-7.03	-5.72	-5.67	-4.72	

Table 7-40

802.11ax (5GHz, 80MHz BW, RU, MIMO) Modulation Interference Factors^{1,2}

		80MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode		RU Index (Data Rate: 34Mbps)								
	0	0 36 37 52 53 60 61 65 66 67							67	
802.11ax	-9.28	-9.41	-8.65	-8.57	-7.34	-7.27	-5.82	-4.82	-4.77	-4.69

Table 7-41

Simultaneous 2.4GHz and 5GHz WIFI Modulation Interference Factors^{1,2,3}

#	5 GH	z WIFI	2.4 GH	Iz WIFI	rence Factors (-)
Tx	[dE	3m]	[dE	3m]	Measured MIF (dB)
1.4	Ant1	Ant2	Ant1	Ant2	
2	х	•	•	x	-4.68
2	-	х	х	-	-4.68
2	х	-	х	-	-4.67
2	-	х	-	х	-4.70
3	х	х	х	-	-4.70
3	х	х	-	х	-4.72
3	х	-	х	х	-5.19
3	-	х	х	х	-5.18
4	х	х	х	x	-4.70

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WLAN MIF values were found to be independent of the transmit channel.

³ Note: The configuration for each scenario (e.g. bandwidth, data rate, etc.) was determined using the worst-case configuration from SISO and MIMO MIF measurements.

8. RF CONDUCTED POWER MEASUREMENTS

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

II. HAC Measurement Conditions

Output Power Verification

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 8-1 for air interface specific settings of transmit power parameters.

Table 8-1
Power Control Parameters and Settings by Air Interface

Air Interface:	Parameter Name:	Parameter Set To:		
CDMA	Power Control Bits	"All Up"		
GSM	PCL	GSM850: "5"; GSM1900: "0"		
UMTS	TPC	"All 1's"		
LTE	TPC	"Max Power"		
WIFI	PLS	Mfr Specified		

III. Setup Used to Measure RF Conducted Powers

Power measurements for licensed modes were performed using a base station simulator under digital average power. Power measurements for unlicensed modes were performed using a power meter and power sensor.



Figure 8-1
Power Measurement Setup for licensed modes

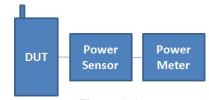


Figure 8-2
Power Measurement Setup for unlicensed modes

IV. CDMA Conducted Powers

	V. OBIIIA GOTIGUOTEG I GWETS													
Band	Channel	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC	MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
	1013	824.7	24.47	24.40	24.48	24.45	24.44	24.43	24.45	24.42	24.48	24.42	24.44	24.50
Cellular	384	836.52	24.52	24.47	24.50	24.54	24.48	24.43	24.49	24.49	24.51	24.47	24.51	24.51
	777	848.31	24.64	24.65	24.63	24.65	24.61	24.54	24.60	24.60	24.60	24.62	24.63	24.41
	25	1851.25	24.04	24.05	24.04	24.05	24.12	23.96	24.05	24.04	23.92	24.03	24.00	24.30
PCS	600	1880	24.12	24.12	24.12	24.13	24.19	24.08	24.12	24.10	24.04	24.05	24.07	23.89
	1175	1908.75	24.01	23.98	24.11	23.98	23.98	23.90	24.10	24.05	23.93	23.85	23.90	24.02

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V. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot
	128	32.47	26.63
GSM 850	190	32.28	26.63
	251	32.45	26.40
	512	29.51	25.52
GSM 1900	661	29.54	25.71
	810	29.44	25.63

VI. UMTS Conducted Powers

Mode	3GPP 34.121 Subtest	Cellu	Cellular Band [dBm] AWS Band [dB				Bm] PCS Ban		S Band [di	nd [dBm]	
	Subtest	4132	4183	4233	1312	1412	1513	9262	9400	9538	
WCDMA	12.2 kbps RMC	24.75	24.80	24.93	23.92	23.93	23.71	24.20	24.27	24.14	
WCDIVIA	12.2 kbps AMR	24.78	24.82	24.94	23.96	23.96	23.74	24.23	24.30	24.16	
HSUPA	Subtest 1	23.80	23.86	24.02	23.01	23.00	22.81	23.20	23.22	23.25	

VII. **LTE Conducted Powers**

a. LTE Band 12

Table 8-2 LTE Band 12 (707.5MHz) Conducted Powers - 10MHz Bandwidth

Modulation	RB Size	RB Offset	Mid Channel 23095 (707.5 MHz) Conducted Power [dBm]	MPR Allowed per . 3GPP [dB]	MPR [dB]
	1	0	24.83		0
	1	25	24.60	0	0
	1	49	24.74		0
QPSK	25	0	23.90		1
	25	12	23.88	0-1	1
	25	25	23.88	0-1	1
	50	0	23.89		1
	1	0	24.07		1
	1	25	24.03	0-1	1
	1	49	23.99		1
16QAM	25	0	22.88		2
	25	12	22.87	0-2	2
	25	25	22.85		2
	50	0	22.88		2
	1	0	23.08		2
	1	25	22.92	0-2	2
	1	49	22.99		2
64QAM	25	0	21.89		3
	25	12	21.88	0-3	3
	25	25	21.82	0-3	3
	50	0	21.89		3
	1	0	19.96		5
	1	25	19.90		5
	1	49	19.85		5
256QAM	25	0	19.88	0-5	5
	25	12	19.84		5
	25	25	19.84		5
	50	0	19.86		5

Note: Since LTE Band 12 at 10MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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Table 8-3 LTE Band 12 (707.5MHz) Conducted Powers – 5MHz Bandwidth

		i - Daila	12 (10110111112	<i>j</i> Conducted F	011010 0111111	Banawiath	
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	23035 (701.5 MHz)	23095 (707.5 MHz)	23155 (713.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm	n]		
	1	0	24.69	24.54	24.53		0
	1	12	24.72	24.63	24.68	0	0
	1	24	24.76	24.63	24.45		0
QPSK	12	0	23.84	23.68	23.70		1
	12	6	23.88	23.76	23.73	0-1	1
	12	13	23.80	23.75	23.77		1
	25	0	23.89	23.72	23.69		1
	1	0	24.04	23.94	23.86		1
	1	12	24.15	24.00	24.02	0-1	1
	1	24	24.06	23.97	24.01		1
16QAM	12	0	22.86	22.66	22.69	0-2	2
	12	6	22.86	22.78	22.77		2
	12	13	22.89	22.71	22.72		2
	25	0	22.80	22.71	22.75		2
	1	0	22.89	22.76	22.84		2
	1	12	22.99	22.88	22.91	0-2	2
	1	24	22.98	22.91	22.88		2
64QAM	12	0	21.90	21.69	21.66		3
	12	6	21.92	21.79	21.74	0-3	3
	12	13	21.86	21.75	21.77	0-3	3
	25	0	21.86	21.74	21.72		3
	1	0	19.89	19.69	19.77		5
	1	12	19.85	19.81	19.83	0-5	5
	1	24	19.81	19.78	19.78		5
256QAM	12	0	19.88	19.70	19.68		5
	12	6	19.89	19.97	19.72		5
	12	13	19.83	19.77	19.74	1	5
	25	0	19.88	19.75	19.73		5

Table 8-4 LTE Band 12 (707.5MHz) Conducted Powers – 3MHz Bandwidth

	_		(
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	Offset 23025 23095 23165 (700.5 MHz) (707.5 MHz) (714.5 MHz)			MPR Allowed per 3GPP [dB]	MPR [dB]
					SGPF [UD]		
		_		Conducted Power [dBn	•		_
	1	0	24.67	24.57	24.55		0
	1	7	24.66	24.56	24.64	0	0
	1	14	24.44	24.51	24.48		0
QPSK	8	0	23.62	23.60	23.59		1
	8	4	23.71	23.74	23.69	0-1	1
	8	7	23.68	23.63	23.67		1
	15	0	23.80	23.75	23.80		1
	1	0	24.06	23.86	23.89		1
	1	7	24.09	24.00	23.95	0-1	1
	1	14	24.04	24.03	24.05		1
16QAM	8	0	22.89	22.69	22.68	0-2	2
	8	4	22.87	22.77	22.79		2
	8	7	22.81	22.71	22.76		2
	15	0	22.86	22.70	22.75		2
	1	0	22.98	22.83	22.85		2
	1	7	22.96	22.88	22.86	0-2	2
	1	14	22.98	22.96	22.86		2
64QAM	8	0	21.89	21.65	21.62		3
	8	4	21.87	21.77	21.73	0-3	3
	8	7	21.80	21.67	21.75	0-3	3
	15	0	21.87	21.73	21.75		3
	1	0	19.88	19.77	19.78		5
	1	7	19.83	19.82	19.82		5
	1	14	19.83	19.74	19.82		5
256QAM	8	0	19.89	19.70	19.75	0-5	5
	8	4	19.90	19.80	19.84		5
	8	7	19.85	19.82	19.80		5
	15	0	19.93	19.77	19.84		5

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Table 8-5 LTE Band 12 (707.5MHz) Conducted Powers - 1.4MHz Bandwidth

			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	23017	23095	23173	MPR Allowed per	MPR [dB]
Modulation	IND GIZE	IND ORIGIN	(699.7 MHz)	(707.5 MHz)	(715.3 MHz)	3GPP [dB]	iiii it [ub]
				Conducted Power [dBn			
	1	0	24.77	24.61	24.52		0
	1	2	24.87	24.63	24.55		0
	1	5	24.78	24.53	24.33	0	0
QPSK	3	0	24.70	24.56	24.42	1	0
	3	2	24.74	24.62	24.42		0
	3	3	24.65	24.57	24.34		0
	6	0	23.87	23.74	23.59	0-1	1
	1	0	24.01	23.92	23.88		1
	1	2	24.17	23.29	23.98	0-1	1
	1	5	24.07	23.96	23.81		1
16QAM	3	0	23.86	23.74	23.62	0-1	1
	3	2	23.93	23.68	23.72		1
	3	3	23.81	23.63	23.62		1
	6	0	22.80	22.67	22.88	0-2	2
	1	0	22.92	22.85	22.70		2
	1	2	22.98	22.84	22.84		2
	1	5	22.87	22.76	22.80	0-2	2
64QAM	3	0	22.86	22.72	22.60	0-2	2
	3	2	22.96	22.75	22.80		2
	3	3	22.88	22.70	22.77		2
	6	0	21.76	21.66	21.60	0-3	3
	1	0	20.00	19.92	19.85		5
	1	2	20.05	19.99	19.94	1	5
	1	5	20.09	19.89	19.91		5
256QAM	3	0	20.01	19.88	19.82	0-5	5
	3	2	20.04	19.92	19.95		5
	3	3	19.95	19.88	19.92		5
	6	0	19.97	19.82	19.85		5

b. LTE Band 13

Table 8-6 LTE Band 13 (780.0MHz) Conducted Powers - 10MHz Bandwidth

			Mid Channel		
Modulation	RB Size	RB Offset	23230 (782.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]		
	1	0	25.11		0
	1	25	24.96	0	0
	1	49	24.89		0
QPSK	25	0	24.18		1
	25	12	24.16	0-1	1
	25	25	24.07	0-1	1
	50	0	24.16		1
	1	0	24.38		1
	1	25	24.21	0-1	1
	1	49	24.08		1
16QAM	25	0	23.13		2
	25	12	23.13	0-2	2
	25	25	23.06	0-2	2
	50	0	23.11		2
	1	0	23.33		2
	1	25	23.17	0-2	2
	1	49	23.08		2
64QAM	25	0	22.15		3
	25	12	22.12	0-3	3
	25	25	22.04	0-3	3
	50	0	22.11		3
	1	0	20.32		5
1	1	25	20.17		5
	1	49	20.02		5
256QAM	25	0	20.23	0-5	5
1	25	12	20.16		5
	25	25	20.10		5
	50	0	20.15		5

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Table 8-7 LTE Band 13 (780.0MHz) Conducted Powers - 5MHz Bandwidth

Modulation	RB Size	RB Offset	Mid Channel 23230 (782.0 MHz) Conducted Power	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	[dBm] 25.08		0
	1	12	25.15	0	0
	1	24	24.81	U	0
QPSK	12	0	24.01		1
QFSK	12	6	24.17		1
	12	13	23.99	0-1	1
	25	0	24.05		1
	1	0	24.30		1
	1	12	24.18	0-1	1
	1	24	24.10	0-1	1
16QAM	12	0	23.37		2
1000	12	6	23.30		2
	12	13	23.25	0-2	2
	25	0	23.29		2
	1	0	23.29		2
	1	12	22.87	0-2	2
	1	24	22.91		2
64QAM	12	0	22.44		3
	12	6	22.36	0.0	3
	12	13	22.30	0-3	3
	25	0	22.29		3
	1	0	20.30		5
	1	12	20.21		5
	1	24	20.10		5
256QAM	12	0	20.24	0-5	5
	12	6	20.13		5
	12	13	20.10		5
	25	0	20.14		5

Note: Since LTE Band 13 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

c. LTE Band 14

Table 8-8 LTE Band 14 (793.0MHz) Conducted Powers - 10MHz Bandwidth

	(Mid Channel		
Modulation	RB Size	RB Offset	23330 (793.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]	3GPP [db]	
	1	0	24.83		0
	1	25	24.58	0	0
	1	49	24.71		0
QPSK	25	0	23.91		1
	25	12	23.86	0-1	1
	25	25	23.80	0-1	1
	50	0	23.86		1
	1	0	24.30		1
	1	25	24.13	0-1	1
	1	49	23.96		1
16QAM	25	0	23.00		2
	25	12	22.95	0-2	2
	25	25	22.88	0-2	2
	50	0	22.92		2
	1	0	23.29		2
	1	25	23.07	0-2	2
	1	49	23.00		2
64QAM	25	0	22.00		3
	25	12	21.96	0-3	3
	25	25	21.85	0-3	3
	50	0	21.93		3
	1	0	20.20		5
	1	25	20.00		5
	1	49	19.93		5
256QAM	25	0	19.99	0-5	5
	25	12	19.94		5
	25	25	19.85		5
	50	0	19.97	1	5

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Table 8-9 LTE Band 14 (793.0MHz) Conducted Powers - 5MHz Bandwidth

	(. •			
			Mid Channel		
Modulation	RB Size	RB Offset	23330 (793.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power	JOFF [UD]	
			[dBm]		
	1	0	24.80		0
	1	12	24.90	0	0
	1	24	24.65		0
QPSK	12	0	24.11		1
	12	6	24.17	0-1	1
	12	13	24.20	0-1	1
	25	0	24.11		1
	1	0	24.03		1
	1	12	24.04	0-1	1
	1	24	24.10		1
16QAM	12	0	23.15		2
	12	6	23.46	0-2	2
	12	13	23.23	0-2	2
	25	0	23.12		2
	1	0	23.16		2
	1	12	23.28	0-2	2
	1	24	23.23		2
64QAM	12	0	22.13		3
	12	6	22.19	0-3	3
	12	13	22.15	0-3	3
	25	0	22.14		3
	1	0	19.97		5
	1	12	20.07		5
	1	24	20.07		5
256QAM	12	0	19.93	0-5	5
	12	6	19.98		5
	12	13	20.00		5
	25	0	20.01		5

Note: Since LTE Band 14 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

d. LTE Band 26

Table 8-10 LTE Band 26 (831.5MHz) Conducted Powers – 15MHz Bandwidth

L Dalla	20 (00 1		Oonaactea i	OWCIS TOIL	III IZ Ballawic
Modulation	RB Size	RB Offset	Mid Channel 26865 (831.5 MHz) Conducted Power	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	25.00		0
	1	36	24.99	0	0
	1	74	24.97		0
QPSK	36	0	24.16		1
	36	18	24.12		1
	36	37	24.07	0-1	1
	75	0	24.10		1
	1	0	24.08		1
	1	36	23.99	0-1	1
	1	74	24.04		1
16QAM	36	0	23.03	0-2	2
	36	18	22.97		2
	36	37	23.02	0-2	2
	75	0	22.91		2
	1	0	22.99		2
	1	36	22.96	0-2	2
	1	74	22.95		2
64QAM	36	0	21.99		3
	36	18	21.83	0-3	3
	36	37	21.83	0-3	3
	75	0	21.89		3
	1	0	19.92		5
	1	36	19.95		5
	1	74	19.92		5
256QAM	36	0	20.01	0-5	5
	36	18	20.05		5
	36	37	19.83		5
	75	0	19.93		5

Note: Since LTE Band 26 at 15MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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Table 8-11 LTE Band 26 (831.5MHz) Conducted Powers - 10MHz Bandwidth

LTE Ballu 26 (63 1.3MHz) Collucted Powers – Towinz Balluwidti								
			Low Channel	Mid Channel	High Channel			
Modulation	RB Size	RB Offset	26740 (819.0 MHz)	26865 (831.5 MHz)	26990 (844.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]	
				Conducted Power [dBm		, ,,,,,		
	1	0	25.28	25.21	25.14		0	
	1	25	25.03	25.05	24.94	0	0	
	1	49	25.07	24.90	24.98		0	
QPSK	25	0	24.18	24.10	24.05		1	
	25	12	24.17	24.02	24.03	0-1	1	
	25	25	24.13	24.05	23.98	0-1	1	
	50	0	24.11	24.02	24.03		1	
	1	0	24.26	24.02	24.04		1	
	1	25	24.32	23.88	23.95	0-1	1	
	1	49	24.36	23.82	23.96		1	
16QAM	25	0	23.12	23.79	23.12		2	
	25	12	23.20	23.11	23.13	0-2	2	
	25	25	23.11	23.08	23.10	0-2	2	
	50	0	23.09	23.02	23.02		2	
	1	0	23.08	22.91	23.10		2	
	1	25	22.83	22.94	22.91	0-2	2	
	1	49	22.77	22.89	22.86		2	
64QAM	25	0	21.73	21.90	21.86		3	
	25	12	21.76	21.90	21.91		3	
	25	25	21.48	21.88	21.90	0-3	3	
	50	0	21.80	21.92	21.86		3	
	1	0	19.89	19.86	19.91		5	
	1	25	19.81	19.95	19.91	1	5	
	1	49	19.54	19.91	19.95	1	5	
256QAM	25	0	19.75	19.83	19.90	0-5	5	
	25	12	19.74	20.00	19.93	1	5	
	25	25	19.62	19.91	19.82	1	5	
ŀ	50	0	19.71	19.99	19.79	1	5	

Table 8-12 LTE Band 26 (831.5MHz) Conducted Powers – 5MHz Bandwidth

LIL Dalid 20 (031.3Will2) Colludcted Fowers - Swill2 Dalidwidth								
			Low Channel	Mid Channel	High Channel	MDD Allersed seen		
Modulation	RB Size	RB Offset	26715 (816.5 MHz)	26865 (831.5 MHz)	27015 (846.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]	
			(Conducted Power [dBm]			
	1	0	25.06	24.88	24.98		0	
	1	12	25.10	24.87	25.02	0	0	
	1	24	25.14	24.98	25.05		0	
QPSK	12	0	24.14	24.01	23.95		1	
	12	6	24.16	24.02	24.04	0-1	1	
	12	13	24.13	24.00	23.98	0-1	1	
	25	0	24.17	23.95	23.98		1	
	1	0	24.49	24.07	24.05		1	
	1	12	24.21	24.08	24.06	0-1	1	
	1	24	24.19	24.15	24.08		1	
16QAM	12	0	23.32	23.09	23.01		2	
	12	6	23.42	23.08	23.07	0-2	2	
	12	13	23.28	23.23	23.02	0-2	2	
	25	0	23.21	23.20	23.04		2	
	1	0	22.70	22.98	22.73		2	
	1	12	22.77	22.87	22.84	0-2	2	
	1	24	22.75	22.85	22.83		2	
64QAM	12	0	21.50	21.79	21.42		3	
	12	6	21.71	21.85	21.75	0-3	3	
	12	13	21.82	21.79	21.65	0-3	3	
	25	0	21.67	21.65	21.73		3	
	1	0	19.72	19.95	19.68		5	
	1	12	19.92	19.88	19.75		5	
	1	24	19.70	19.81	19.70	1	5	
256QAM	12	0	19.64	19.78	19.70	0-5	5	
	12	6	19.70	19.68	19.74		5	
	12	13	19.74	19.42	19.77		5	
	25	0	19.84	19.83	19.68		5	

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Table 8-13 LTE Band 26 (831.5MHz) Conducted Powers – 3MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	26705 (815.5 MHz)	26865 (831.5 MHz)	27025 (847.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm	1]		
	1	0	24.89	24.93	24.88		0
	1	7	24.90	24.96	24.85	0	0
	1	14	24.86	24.96	24.80		0
QPSK	8	0	23.98	23.99	23.97		1
	8	4	24.14	24.06	23.90	0-1	1
	8	7	24.13	24.02	23.93	0-1	1
	15	0	24.05	23.99	23.92		1
	1	0	23.97	24.16	23.77		1
	1	7	23.97	24.15	23.73	0-1	1
	1	14	23.95	24.19	23.67		1
16QAM	8	0	23.25	23.05	23.10		2
	8	4	23.22	23.10	23.02	0-2	2
	8	7	23.04	23.09	23.09	0-2	2
	15	0	23.03	23.10	23.00		2
	1	0	22.77	22.65	22.80		2
	1	7	22.89	22.76	22.79	0-2	2
	1	14	22.83	22.67	22.68		2
64QAM	8	0	21.75	21.88	21.74		3
	8	4	21.68	21.75	21.53	0-3	3
	8	7	21.33	21.63	21.57	0-3	3
	15	0	21.89	21.87	21.79		3
	1	0	19.81	19.73	19.76		5
	1	7	19.92	19.92	19.87]	5
	1	14	19.88	19.77	19.72		5
256QAM	8	0	19.78	19.63	19.82	0-5	5
	8	4	19.89	19.81	19.76		5
	8	7	19.90	19.73	19.70]	5
L							

Table 8-14 LTE Band 26 (831.5MHz) Conducted Powers – 1.4MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	26697	26865	27033	MPR Allowed per	MPR [dB]
modulation	IND OIL	IND CHOCK	(814.7 MHz)	(831.5 MHz)	(848.3 MHz)	3GPP [dB]	iii it [ub]
			(Conducted Power [dBm	•		
	1	0	24.95	25.01	24.81		0
	1	2	25.05	25.11	24.88		0
	1	5	24.95	25.10	24.80	0	0
QPSK	3	0	24.96	24.77	24.73	U	0
	3	2	25.02	24.94	24.83		0
	3	3	24.98	24.82	24.78		0
	6	0	23.98	24.11	23.94	0-1	1
	1	0	24.27	23.89	23.83		1
	1	2	24.37	23.88	23.89		1
	1	5	24.33	23.20	23.78	0-1	1
16QAM	3	0	24.11	23.74	23.93	0-1	1
	3	2	23.98	23.83	23.93		1
	3	3	24.10	23.92	23.85		1
	6	0	23.26	23.10	23.05	0-2	2
	1	0	22.72	22.67	22.76		2
	1	2	22.86	22.76	22.92		2
	1	5	22.78	22.69	22.89	0-2	2
64QAM	3	0	22.68	22.59	22.74	0-2	2
	3	2	22.80	22.69	22.76		2
	3	3	22.74	22.66	22.69		2
	6	0	21.80	21.71	21.77	0-3	3
	1	0	19.80	19.66	19.82		5
	1	2	19.91	19.57	19.91		5
	1	5	19.90	19.73	19.86		5
256QAM	3	0	19.75	19.74	19.82	0-5	5
	3	2	19.96	19.84	19.84		5
	3	3	19.73	19.79	19.85		5
	6	0	19.84	19.73	19.74		5

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e. LTE Band 5

Table 8-15 LTE Band 5 (836.5MHz) Conducted Powers - 10MHz Bandwidth

	u		Mid Channel		iz Banaman
Modulation	RB Size	RB Offset	20525 (836.5 MHz) Conducted Power	MPR Allowed per 3GPP [dB]	MPR [dB]
			[dBm]		
QPSK	1	0	24.94		0
	1	25	24.77	0	0
	1	49	24.75		0
	25	0	23.98		1
	25	12	23.94	0.4	1
	25	25	23.87	0-1	1
	50	0	23.96		1
16QAM	1	0	24.17		1
	1	25	24.10	0-1	1
	1	49	24.10		1
	25	0	22.98		2
	25	12	22.91	0-2	2
	25	25	22.86	0-2	2
	50	0	22.92		2
	1	0	23.15		2
	1	25	23.06	0-2	2
	1	49	23.02		2
64QAM	25	0	21.94		3
	25	12	21.92	0-3	3
	25	25	21.86	0-3	3
	50	0	21.94		3
	1	0	20.19		5
256QAM	1	25	20.01		5
	1	49	20.02		5
	25	0	19.93	0-5	5
	25	12	19.94		5
	25	25	19.84		5
	50	0	19.95		5

Note: Since LTE Band 5 at 10MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 8-16 LTE Band 5 (836.5MHz) Conducted Powers – 5MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20425 (826.5 MHz)	20525 (836.5 MHz)	20625 (846.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm]			
QPSK	1	0	24.90	24.90	24.92	0	0
	1	12	24.93	24.88	24.93		0
	1	24	24.93	24.93	24.94		0
	12	0	24.02	24.08	24.10	0-1	1
	12	6	24.14	24.05	24.17		1
	12	13	24.13	24.13	24.22		1
	25	0	24.14	24.10	24.12		1
	1	0	24.22	24.27	24.35	0-1	1
	1	12	24.26	24.22	24.33		1
	1	24	24.31	24.41	24.31		1
16QAM	12	0	23.06	23.07	23.12	0-2	2
	12	6	23.18	23.17	23.26		2
	12	13	23.21	23.21	23.25		2
	25	0	23.10	23.07	23.12		2
	1	0	23.18	23.21	23.26	0-2	2
	1	12	23.17	23.24	23.25		2
	1	24	23.25	23.09	23.50		2
64QAM)AM 12	0	22.06	22.07	22.10		3
	12	6	22.19	22.12	22.18		3
12 25	12	13	22.23	22.19	22.27		3
	25	0	22.11	22.04	22.17		3
	1	0	19.83	19.79	20.23	0-5	5
	1	12	19.93	19.92	20.07		5
	1	24	19.85	20.00	20.02		5
256QAM	12	0	19.65	19.67	19.80		5
	12	6	19.78	19.76	19.94		5
	12	13	19.86	19.85	19.95		5
	25	0	19.82	19.86	19.96		5

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Table 8-17 LTE Band 5 (836.5MHz) Conducted Powers – 3MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20415 (825.5 MHz)	20525 (836.5 MHz)	20635 (847.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm]		
	1	0	24.78	24.92	24.85		0
	1	7	24.88	24.93	24.86	0	0
	1	14	24.94	24.94	24.93		0
QPSK	8	0	24.03	24.09	24.00		1
	8	4	24.11	24.18	24.16	0-1	1
	8	7	24.08	24.21	24.12	0-1	1
	15	0	24.11	24.15	24.04		1
	1	0	24.10	24.26	24.19		1
	1	7	24.05	24.33	24.28	0-1	1
	1	14	24.18	24.39	24.38		1
16QAM	8	0	23.21	23.12	23.11		2
	8	4	23.27	23.27	23.32	0-2	2
	8	7	23.17	23.24	23.21		2
	15	0	23.15	23.19	23.09		2
	1	0	23.14	23.06	23.26		2
	1	7	23.25	23.38	23.04	0-2	2
	1	14	23.19	23.15	23.25		2
64QAM	8	0	22.09	22.09	22.09		3
	8	4	22.19	22.25	22.19	0-3	3
	8	7	22.25	22.24	22.15	0-3	3
	15	0	22.09	22.17	22.12		3
	1	0	19.83	19.76	19.86		5
	1	7	19.79	19.80	19.99		5
	1	14	19.84	20.16	20.05		5
256QAM	8	0	19.77	19.78	19.87	0-5	5
	8	4	19.83	19.80	19.96		5
	8	7	19.88	19.63	19.97		5
	15	0	19.75	19.86	19.96		5

Table 8-18 LTE Band 5 (836.5MHz) Conducted Powers - 1.4MHz Bandwidth

			- (:, ·				
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20407 (824.7 MHz)	20525 (836.5 MHz)	20643 (848.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm]		
	1	0	24.74	24.81	24.84		0
	1	2	24.85	24.81	24.83		0
	1	5	24.80	24.87	24.85		0
QPSK	3	0	24.84	24.82	24.83	0	0
	3	2	24.94	24.93	24.96		0
	3	3	24.88	24.86	24.92		0
	6	0	24.05	23.98	24.03	0-1	1
	1	0	23.99	24.21	24.16		1
	1	2	24.36	24.12	24.15	0-1	1
	1	5	24.15	24.14	24.27		1
16QAM	3	0	24.01	23.91	24.03		1
	3	2	24.05	23.88	24.11		1
	3	3	23.94	24.10	24.03		1
	6	0	23.00	22.94	23.14	0-2	2
	1	0	22.98	22.87	23.30		2
	1	2	23.05	23.12	23.20		2
	1	5	23.08	23.29	23.22	0-2	2
64QAM	3	0	22.96	23.19	23.20	0-2	2
	3	2	23.08	23.11	23.05		2
	3	3	23.02	23.00	23.19		2
	6	0	21.99	21.96	21.92	0-3	3
	1	0	19.59	19.69	20.10		5
	1	2	19.68	19.84	20.06		5
	1	5	19.67	19.87	20.01		5
256QAM	3	0	19.56	19.78	19.96	0-5	5
	3	2	19.48	19.87	20.08		5
	3	3	19.66	19.83	20.00		5
	6	0	19.62	19.73	19.79	1	3

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f. LTE Band 66

Table 8-19 LTE Band 66 (1745.0MHz) Conducted Powers – 20MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	132072 (1720.0 MHz)	132322 (1745.0 MHz)	132572 (1770.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm]		
	1	0	24.40	24.22	24.19		0
	1	50	24.32	24.17	24.05	0	0
	1	99	24.51	24.13	24.08		0
QPSK	50	0	23.57	23.36	23.30		1
	50	25	23.52	23.34	23.31	0-1	1
	50	50	23.44	23.29	23.26	0-1	1
	100	0	23.52	23.33	23.28		1
	1	0	23.67	23.56	23.48		1
	1	50	23.58	23.45	23.36	0-1	1
	1	99	23.63	23.52	23.42		1
16QAM	50	0	22.59	22.38	22.31		2
	50	25	22.50	22.36	22.28	0-2	2
	50	50	22.42	22.31	22.28		2
	100	0	22.49	22.31	22.30		2
	1	0	22.72	22.53	22.47		2
	1	50	22.60	22.46	22.33	0-2	2
	1	99	22.64	22.46	22.36		2
64QAM	50	0	21.58	21.36	21.34		3
	50	25	21.51	21.34	21.31	0-3	3
	50	50	21.43	21.31	21.33	0-3	3
	100	0	21.46	21.31	21.30		3
	1	0	19.60	19.45	19.36		5
	1	50	19.41	19.32	19.23		5
	1	99	19.45	19.29	19.28	0-5	5
256QAM	50	0	19.53	19.37	19.27		5
	50	25	19.45	19.32	19.33		5
	50	50	19.34	19.28	19.34		5
	100	0	19.46	19.36	19.28		5

Table 8-20 LTE Band 66 (1745.0MHz) Conducted Powers - 15MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	132047 (1717.5 MHz)	132322 (1745.0 MHz)	132597 (1772.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.87	23.98	24.40		0
	1	36	23.75	24.03	24.37	0	0
	1	74	23.88	24.10	24.27		0
QPSK	36	0	23.02	23.01	23.42		1
	36	18	23.06	23.21	23.25	0-1	1
	36	37	23.01	23.23	23.41	0-1	1
[75	0	23.11	23.25	23.49		1
	1	0	23.20	23.31	23.58		1
	1	36	23.03	23.25	23.65	0-1	1
1	1	74	23.01	22.98	23.40		1
16QAM	36	0	21.91	22.04	22.43		2
	36	18	21.98	22.21	22.42	0-2	2
[36	37	21.90	22.19	22.41		2
	75	0	21.97	22.20	22.40		2
	1	0	21.95	22.31	22.46		2
	1	36	21.90	22.20	22.46	0-2	2
	1	74	21.92	22.19	22.40		2
64QAM	36	0	20.94	21.12	21.45		3
	36	18	20.90	21.22	21.50	0-3	3
	36	37	20.97	21.20	21.45	0-3	3
	75	0	20.94	21.22	21.44		3
	1	0	18.88	19.10	19.37		5
Ī	1	36	18.86	19.28	19.43		5
	1	74	18.87	19.48	19.37		5
256QAM	36	0	18.99	19.21	19.32	0-5	5
ļ	36	18	18.94	19.23	19.42	Ī	5
ĺ	36	37	18.99	19.19	19.44	Ī	5
	75	0	18.90	19.29	19.43		5

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Table 8-21 LTE Band 66 (1745.0MHz) Conducted Powers – 10MHz Bandwidth

					High Channel		
			Low Channel 132022	Mid Channel 132322	High Channel 132622	MPR Allowed per	
Modulation	RB Size	RB Offset	(1715.0 MHz)	(1745.0 MHz)	(1775.0 MHz)	3GPP [dB]	MPR [dB]
				Conducted Power [dBm			
	1	0	23.76	24.25	24.24		0
	1	25	23.83	24.34	24.35	0	0
	1	49	24.36	24.32	24.24		0
QPSK	25	0	22.87	23.37	23.11		1
	25	12	22.98	23.51	23.43	0.4	1
	25	25	22.92	23.41	23.47	0-1	1
	50	0	23.01	23.41	23.50		1
	1	0	22.84	23.46	23.32		1
	1	25	22.90	23.59	23.57	0-1	1
	1	49	22.91	23.47	23.47		1
16QAM	25	0	21.92	22.36	22.29		2
	25	12	21.85	22.35	22.31	0-2	2
	25	25	21.88	22.35	22.33		2
	50	0	21.90	22.33	22.37		2
	1	0	21.85	22.30	22.32	0-2	2
	1	25	21.86	22.31	22.38		2
	1	49	21.82	22.48	22.39		2
64QAM	25	0	20.82	21.28	21.38		3
	25	12	20.87	21.44	21.32	0-3	3
	25	25	20.82	21.37	21.26		3
	50	0	20.86	21.32	21.38		3
	1	0	18.79	19.22	19.17	<u> </u>	5
	1	25	19.05	19.03	19.47	0-5	5
	1	49	18.76	19.27	19.22		5
256QAM	25	0	18.91	19.29	19.34		5
	25	12	18.95	19.32	19.25		5
	25	25	18.90	19.30	19.28		5
	50	0	18.76	19.33	19.31		5

Table 8-22 LTE Band 66 (1745.0MHz) Conducted Powers – 5MHz Bandwidth

		Low Channel	Mid Channel	High Channel			
Modulation	RB Size RB Offset	RB Offset	131997 (1712.5 MHz)	132322 (1745.0 MHz)	132647 (1777.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.98	24.24	23.96		0
	1	12	23.96	24.37	24.02	0	0
	1	24	24.02	24.38	24.14		0
QPSK	12	0	22.82	23.41	23.78		1
	12	6	22.99	23.31	23.03	0-1	1
	12	13	23.22	23.44	23.11	0-1	1
	25	0	23.11	23.26	23.01		1
	1	0	23.20	23.43	23.25		1
	1	12	23.24	23.17	23.34	0-1	1
	1	24	23.12	23.30	23.44		1
16QAM	12	0	21.90	22.28	21.92		2
	12	6	22.00	22.37	22.13	0-2	2
	12	13	22.08	22.27	22.11	0-2	2
	25	0	22.05	22.31	22.08		2
	1	0	21.94	22.26	21.89		2
	1	12	22.07	22.30	21.83	0-2	2
	1	24	22.03	22.39	22.11	1	2
64QAM	12	0	20.95	21.13	21.14		3
	12	6	21.12	21.18	21.17	0-3	3
	12	13	21.01	21.26	21.15	0-3	3
	25	0	20.99	21.30	21.03		3
	1	0	18.79	19.41	19.16		5
	1	12	18.92	19.32	19.05		5
	1	24	18.90	19.23	19.05		5
256QAM	12	0	18.87	19.12	19.11	0-5	5
	12	6	18.97	19.32	19.20		5
	12	13	18.96	19.36	19.13]	5
	25	0	18.95	19.24	19.09		5

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Table 8-23 LTE Band 66 (1745.0MHz) Conducted Powers – 3MHz Bandwidth

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			Low Channel	Mid Channel	High Channel		
Modulation RB S	RB Size	RB Offset	131987 (1711.5 MHz)	132322 (1745.0 MHz)	132657 (1778.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	24.01	24.36	24.39		0
	1	7	24.14	24.31	24.48	0	0
	1	14	24.20	24.30	24.53		0
QPSK	8	0	22.88	23.27	23.47		1
	8	4	22.86	23.46	23.60	0-1	1
	8	7	22.95	23.45	23.52	0-1	1
	15	0	22.75	23.46	23.62		1
	1	0	23.22	23.66	23.35	0-1	1
	1	7	23.06	23.49	23.38		1
	1	14	23.14	23.64	23.55		1
16QAM	8	0	22.16	22.27	22.47	0-2	2
	8	4	22.25	22.42	22.60		2
	8	7	22.06	22.44	22.61		2
	15	0	21.65	22.28	22.51		2
	1	0	22.12	22.43	22.55		2
	1	7	22.23	22.66	22.66	0-2	2
	1	14	22.07	22.33	22.54		2
64QAM	8	0	20.92	21.26	21.73		3
	8	4	21.03	21.33	21.43	0-3	3
	8	7	21.07	21.17	21.54	0-3	3
	15	0	21.01	21.44	21.34		3
	1	0	19.11	19.48	19.44		5
	1	7	19.04	19.24	19.68		5
	1	14	19.09	19.31	19.59	Ī	5
256QAM	8	0	19.01	19.40	19.55	0-5	5
	8	4	19.07	19.31	19.42		5
	8	7	19.20	19.17	19.38		5
	15	0	19.11	19.30	19.50		5

Table 8-24 LTE Band 66 (1745.0MHz) Conducted Powers – 1.4MHz Bandwidth

			Low Channel 131979	Mid Channel 132322	High Channel 132665	MPR Allowed per	
Modulation	RB Size	RB Offset	(1710.7 MHz)	(1745.0 MHz)	(1779.3 MHz)	3GPP [dB]	MPR [dB]
				Conducted Power [dBm]			
	1	0	23.98	24.21	24.47		0
	1	2	24.12	24.20	24.52		0
	1	5	24.04	24.28	24.56	1	0
QPSK	3	0	24.06	24.17	24.45	0	0
	3	2	24.05	24.20	24.57		0
	3	3	24.05	24.23	24.48		0
	6	0	23.43	23.19	23.65	0-1	1
	1	0	23.18	23.36	23.54		1
	1	2	23.24	23.22	23.20	0-1	1
	1	5	23.47	23.38	23.58		1
16QAM	3	0	23.01	23.22	23.26		1
	3	2	23.22	23.45	23.38		1
	3	3	23.13	23.36	23.73		1
	6	0	22.00	22.23	22.78	0-2	2
	1	0	22.08	22.31	22.66		2
	1	2	22.17	22.38	22.73		2
	1	5	22.27	22.47	22.81	0-2	2
64QAM	3	0	21.87	22.19	22.25	0-2	2
	3	2	21.81	22.49	22.41		2
	3	3	21.88	22.21	22.60		2
	6	0	21.15	21.34	21.54	0-3	3
	1	0	18.93	19.49	19.72		5
	1	2	19.01	19.16	19.27	0-5	5
	1	5	19.27	19.16	19.43		5
256QAM	3	0	18.92	19.36	19.47		5
	3	2	19.28	19.27	19.51	1	5
	3	3	19.11	19.31	19.34	1	5
ı	6	0	19.17	19.14	19.52	1	5

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g. LTE Band 2

Table 8-25 LTE Band 2 (1880.0MHz) Conducted Powers – 20MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	18700 (1860.0 MHz)	18900 (1880.0 MHz)	19100 (1900.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.74	23.80	23.58		0
	1	50	23.81	23.69	23.68	0	0
	1	99	23.74	23.50	23.40		0
QPSK	50	0	22.94	22.77	22.46		1
	50	25	22.98	22.83	22.54	0-1	1
	50	50	22.96	22.59	22.53	0-1	1
	100	0	22.92	22.78	22.76		1
	1	0	22.81	22.66	22.75		1
	1	50	22.77	22.70	22.78	0-1	1
	1	99	22.87	22.61	22.38		1
16QAM	50	0	21.85	21.64	21.37		2
	50	25	21.88	21.70	21.42	0-2	2
	50	50	21.91	21.46	21.31	0-2	2
	100	0	21.87	21.70	21.29		2
	1	0	21.85	21.65	22.15		2
	1	50	21.93	21.75	22.25	0-2	2
	1	99	21.85	21.70	21.83		2
64QAM	50	0	20.89	20.67	20.87		3
	50	25	20.88	20.75	20.58	0-3	3
	50	50	20.92	20.52	20.55	0-5	3
	100	0	20.88	20.71	20.43		3
	1	0	18.83	18.73	18.78		5
	1	50	18.85	18.70	18.89		5
	1	99	18.85	18.66	18.87		5
256QAM	50	0	18.88	18.68	18.76	0-5	5
	50	25	18.86	18.71	18.75		5
	50	50	18.98	18.86	18.70		5
	100	0	18.80	18.71	18.75		5

Table 8-26 LTE Band 2 (1880.0MHz) Conducted Powers - 15MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	18675 (1857.5 MHz)	18900 (1880.0 MHz)	19125 (1902.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.74	23.88	23.71		0
	1	36	23.72	23.88	23.75	0	0
	1	74	23.82	23.51	23.44		0
QPSK	36	0	22.95	23.02	22.91		1
	36	18	22.98	23.05	22.93	0-1	1
	36	37	23.03	23.08	22.91	0-1	1
[75	0	22.99	23.01	22.94		1
	1	0	23.17	23.19	23.11		1
	1	36	23.03	23.24	23.04	0-1	1
	1	74	23.20	22.80	22.75		1
16QAM	36	0	21.95	22.04	21.89		2
	36	18	21.98	22.06	21.94	0-2	2
	36	37	21.99	22.13	21.99	0-2	2
	75	0	21.94	22.01	21.96		2
	1	0	22.13	22.18	22.09		2
	1	36	22.01	22.21	22.03	0-2	2
	1	74	22.17	21.83	22.16		2
64QAM	36	0	21.00	21.00	20.89		3
	36	18	21.03	21.14	20.97	0-3	3
	36	37	21.08	21.12	21.10	0-3	3
	75	0	21.02	21.06	20.95		3
	1	0	19.02	19.05	18.92		5
	1	36	18.95	18.98	18.92		5
	1	74	18.72	19.04	18.89	0-5	5
256QAM	36	0	18.93	18.94	18.84		5
	36	18	18.92	19.03	18.96		5
İ	36	37	18.96	19.05	18.93	Ī	5
	75	0	18.95	19.01	18.92	İ	5

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Table 8-27 LTE Band 2 (1880.0MHz) Conducted Powers – 10MHz Bandwidth

LIL Band 2 (1000.0Min2) Conducted Fowers - 10Min2 Bandwidth								
			Low Channel	Mid Channel	High Channel			
Modulation	RB Size	RB Offset	18650 (1855.0 MHz)	18900 (1880.0 MHz)	19150 (1905.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]	
			(Conducted Power [dBm]			
	1	0	23.68	23.62	23.71		0	
	1	25	23.68	23.80	23.62	0	0	
	1	49	23.85	23.81	23.40		0	
QPSK	25	0	22.84	22.92	22.81		1	
	25	12	22.86	22.99	22.84	0-1	1	
	25	25	22.84	22.87	22.80	U-1	1	
	50	0	22.93	22.77	22.83		1	
	1	0	22.96	23.11	21.99		1	
	1	25	22.78	23.17	22.91	0-1	1	
	1	49	22.82	23.14	22.96		1	
16QAM	25	0	21.90	21.92	21.85		2	
	25	12	21.88	21.96	21.82	0-2	2	
	25	25	21.81	21.90	21.83	0-2	2	
	50	0	21.82	21.88	21.80		2	
	1	0	21.81	22.03	21.93		2	
	1	25	22.05	22.08	21.89	0-2	2	
	1	49	21.97	22.09	21.83		2	
64QAM	25	0	20.86	20.91	20.80		3	
	25	12	20.87	20.97	20.83	0-3	3	
	25	25	20.85	20.90	20.73	0-3	3	
	50	0	20.87	20.93	20.89		3	
	1	0	18.84	18.89	18.92		5	
	1	25	18.92	18.68	18.83		5	
	1	49	18.84	18.95	18.84		5	
256QAM	25	0	18.81	18.90	18.80	0-5	5	
	25	12	18.87	18.88	18.79		5	
	25	25	18.81	18.85	18.80	<u> </u>	5	
	50	0	18.82	18.83	18.76		5	

Table 8-28 LTE Band 2 (1880.0MHz) Conducted Powers - 5MHz Bandwidth

			Low Channel	Channel Mid Channel High			
Modulation	RB Size	RB Offset	18625 (1852.5 MHz)	18900 (1880.0 MHz)	19175 (1907.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.69	23.72	23.71		0
	1	12	23.63	23.84	23.70	0	0
	1	24	23.81	23.77	23.42	1	0
QPSK	12	0	22.81	22.85	22.84		1
	12	6	22.92	22.84	22.99	0-1	1
	12	13	22.88	22.98	22.95	0-1	1
	25	0	22.85	22.88	22.88		1
	1	0	22.97	22.94	23.09		1
	1	12	23.10	23.10	23.09	0-1	1
16QAM	1	24	23.09	23.28	22.84		1
	12	0	21.87	21.95	21.52		2
	12	6	21.91	21.92	21.96	0-2	2
	12	13	21.98	22.02	21.92	0-2	2
	25	0	21.96	21.91	21.89		2
	1	0	21.99	22.03	21.92		2
	1	12	22.06	22.07	22.03	0-2	2
	1	24	22.02	22.09	21.82		2
64QAM	12	0	20.90	20.86	20.95		3
	12	6	20.95	21.02	20.92	0-3	3
	12	13	20.94	20.90	20.99		3
	25	0	20.88	20.86	20.96		3
	1	0	18.89	18.92	18.91		5
	1	12	18.88	18.97	18.90		5
	1	24	18.93	18.99	18.95	0-5	5
256QAM	12	0	18.77	18.77	18.85		5
	12	6	18.90	18.80	18.91		5
	12	13	18.85	18.86	18.91	<u> </u>	5
	25	0	18.82	18.83	18.87		5

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Table 8-29 LTE Band 2 (1880.0MHz) Conducted Powers – 3MHz Bandwidth

	_	I Dana	Low Channel	Mid Channel	High Channel	Danamati	
Modulation	RB Size	RB Offset	18615 (1851.5 MHz)	18900 (1880.0 MHz)	19185 (1908.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.77	23.79	23.60		0
	1	7	23.70	23.85	23.32	0	0
	1	14	23.83	23.92	23.22		0
QPSK	8	0	22.91	22.89	22.89		1
	8	4	22.96	22.99	22.92	0-1	1
	8	7	22.97	22.95	22.90	0-1	1
	15	0	22.98	22.86	22.86		1
	1	0	23.01	23.16	22.89		1
	1	7	23.07	23.18	22.66	0-1	1
	1	14	23.15	23.15	22.58		1
16QAM	8	0	22.03	22.00	21.94		2
	8	4	22.05	22.03	21.89	0-2	2
	8	7	21.95	22.07	21.91	0-2	2
	15	0	21.96	21.93	21.73		2
	1	0	22.02	22.05	21.65		2
	1	7	22.05	22.12	21.76	0-2	2
	1	14	22.14	22.09	21.54		2
64QAM	8	0	20.89	20.93	20.85		3
	8	4	20.98	20.97	20.96	0-3	3
	8	7	20.95	20.98	20.91] 0-3	3
	15	0	20.91	20.94	20.93		3
	1	0	18.58	18.94	18.84		5
	1	7	18.89	18.99	18.89		5
	1	14	18.93	18.98	18.95] [5
256QAM	8	0	18.93	18.93	18.83	0-5	5
	8	4	18.86	18.97	18.94		5
	8	7	18.87	18.94	18.90		5
	15	0	18.88	18.94	18.87		5

Table 8-30 LTE Band 2 (1880.0MHz) Conducted Powers - 1.4MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	18607 (1850.7 MHz)	18900 (1880.0 MHz)	19193 (1909.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(Conducted Power [dBm]		
	1	0	23.61	23.68	23.27		0
	1	2	23.74	23.69	23.32		0
	1	5	23.73	23.74	23.16	0	0
QPSK	3	0	23.60	23.72	23.22	U	0
	3	2	23.60	23.83	23.22		0
	3	3	23.75	23.75	23.14		0
	6	0	22.77	22.85	22.70	0-1	1
	1	0	22.92	22.98	22.60		1
	1	2	22.99	23.11	22.49		1
	1	5	23.02	23.02	22.32	0-1	1
16QAM	3	0	22.80	22.90	22.37	0-1	1
	3	2	22.87	22.98	22.40		1
	3	3	22.87	22.93	22.33		1
	6	0	21.85	21.84	21.73	0-2	2
	1	0	21.97	21.89	21.94		2
	1	2	22.02	22.04	21.62		2
	1	5	21.99	22.02	21.58	0-2	2
64QAM	3	0	21.83	21.87	21.45	0-2	2
	3	2	21.85	21.90	21.52		2
	3	3	21.82	21.93	21.43		2
	6	0	20.83	20.84	20.77	0-3	3
	1	0	18.85	18.93	18.81		5
	1	2	18.86	18.78	18.79		5
	1	5	18.83	18.72	18.84	1	5
256QAM	3	0	18.87	18.90	18.72	0-5	5
	3	2	18.96	19.13	18.90		5
	3	3	18.83	19.29	18.80		5
	6	0	18.76	18.61	18.61		5

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h. LTE Band 30

Table 8-31 LTE Band 30 (2310.0MHz) Conducted Powers - 10MHz Bandwidth

- I - Daii	a 00 (±0 i	0.0111112	Ochladetea i	OWCIS TOWN	iz Danawiati	
			Mid Channel			
			27710	MPR Allowed per		
Modulation	RB Size	RB Offset	(2310.0 MHz)	3GPP [dB]	MPR [dB]	
			Conducted Power	00[02]		
			[dBm]			
	1	0	23.72		0	
	1	25	23.63	0	0	
	1	49	23.75		0	
QPSK	25	0	22.96		1	
	25	12	22.80	0-1	1	
	25	25	22.87		1	
	50	0	22.85		1	
	1	0	23.19		1	
	1	25	22.92	0-1	1	
	1	49	22.74		1	
16QAM	25	0	21.93		2	
	25	12	21.94	0-2	2	
	25	25	21.84	0-2	2	
	50	0	21.95		2	
	1	0	22.06		2	
	1	25	21.86	0-2	2	
	1	49	21.90		2	
64QAM	25	0	20.98		3	
	25	12	20.88	0-3	3	
	25	25	20.63] 0-3	3	
	50	0	20.65		3	
	1	0	19.13		5	
	1	25	18.85		5	
	1	49	18.80	1	5	
256QAM	25	0	18.94	0-5	5	
	25	12	18.86	1	5	
	25	25	18.91	1	5	
	50	0	18.84	1	5	

Table 8-32 LTE Band 30 (2310.0MHz) Conducted Powers - 5MHz Bandwidth

	. 55 (<u>-5</u> .					
			Mid Channel			
			27710	MPR Allowed per		
Modulation	RB Size	RB Offset	(2310.0 MHz)	3GPP [dB]	MPR [dB]	
			Conducted Power	00 [u.b]		
		-	[dBm]		_	
	1	0	23.82		0	
	1	12	23.84	0	0	
	1	24	23.85		0	
QPSK	12	0	23.08		1	
	12	6	22.94	0-1	1	
	12	13	23.01	0-1	1	
	25	0	22.99		1	
	1	0	23.06		1	
	1	12	23.14	0-1	1	
	1	24	23.03		1	
16QAM	12	0	22.14		2	
	12	6	22.06	0-2	2	
	12	13	21.95	0-2	2	
	25	0	21.93		2	
	1	0	22.09		2	
	1	12	21.84	0-2	2	
	1	24	21.96		2	
64QAM	12	0	21.00		3	
	12	6	21.02	0-3	3	
	12	13	20.87	0-3	3	
	25	0	20.92		3	
	1	0	19.08		5	
	1	12	19.00		5	
	1	24	18.89		5	
256QAM	12	0	18.82	0-5	5	
	12	6	18.94		5	
	12	13	18.92		5	
	25	0	18.82		5	

Note: Since LTE Band 30 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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i. LTE Band 7

Table 8-33 LTE Band 7 (2535.0MHz) Conducted Powers - 20MHz Bandwidth

		(====::::::::::::::::::::::::::::::::::	oonaaotoa i		TIE Ballawiat		
			Low Channel 20850	Mid Channel 21100	High Channel 21350	MPR Allowed per	
Modulation	RB Size	RB Offset	(2510.0 MHz)	(2535.0 MHz)	(2560.0 MHz)	3GPP [dB]	MPR [dB]
				Conducted Power [dBn		00.1 [42]	
	1	0	22.36	22.49	22.32		0
	1	50	22.33	22.46	22.20	0	0
	1	99	22.40	22.37	22.20		0
QPSK	50	0	21.50	21.74	21.50		1
	50	25	21.51	21.69	21.39	0-1	1
	50	50	21.49	21.58	21.34	0-1	1
	100	0	21.48	21.64	21.40		1
	1	0	21.63	21.75	21.66		1
	1	50	21.64	21.70	21.49	0-1	1
	1	99	21.68	21.61	21.54		1
16QAM	50	0	20.50	20.70	20.49		2
	50	25	20.50	20.62	20.40	0-2	2
	50	50	20.46	20.54	20.30	0-2	2
	100	0	20.47	20.59	20.41		2
	1	0	20.57	20.70	20.64		2
	1	50	20.61	20.66	20.52	0-2	2
	1	99	20.62	20.60	20.51		2
64QAM	50	0	19.46	19.69	19.51		3
	50	25	19.48	19.67	19.42	0-3	3
	50	50	19.49	19.54	19.36	0-3	3
	100	0	19.50	19.57	19.42		3
	1	0	17.12	17.39	17.33		5
	1	50	17.18	17.35	17.05		5
	1	99	17.24	17.27	17.01		5
256QAM	50	0	17.13	17.48	17.24	0-5	5
	50	25	17.13	17.45	17.10		5
	50	50	17.16	17.37	16.96		5
1	100	0	17.13	17.44	17.15		5

Table 8-34 LTE Band 7 (2535.0MHz) Conducted Powers - 15MHz Bandwidth

		(2000)		onoro romine Barrannat.		****	
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20825	21100	21375	MPR Allowed per	MPR [dB]
Wodulation	ND Size	KB Oliset	(2507.5 MHz)	(2535.0 MHz)	(2562.5 MHz)	3GPP [dB]	WEN [GD]
				Conducted Power [dBn			
	1	0	22.23	22.49	22.39		0
	1	36	22.31	22.57	22.18	0	0
	1	74	22.32	22.33	22.14		0
QPSK	36	0	21.44	21.72	21.45		1
	36	18	21.56	21.64	21.39	0-1	1
	36	37	21.45	21.56	21.29	0-1	1
	75	0	21.48	21.68	21.37		1
	1	0	21.51	21.82	21.72		1
	1	36	21.52	21.88	21.50	0-1	1
	1	74	21.76	21.67	21.52		1
16QAM	36	0	20.41	20.77	20.44		2
	36	18	20.43	20.73	20.35	0-2	2
	36	37	20.46	20.62	20.26	0-2	2
	75	0	20.44	20.68	20.28		2
	1	0	20.49	20.77	20.70		2
	1	36	20.51	20.65	20.49	0-2	2
	1	74	20.60	20.69	20.32		2
64QAM	36	0	19.45	19.73	19.48		3
	36	18	19.73	19.76	19.39	0-3	3
	36	37	19.47	19.63	19.33	0-3	3
	75	0	19.49	19.66	19.38		3
	1	0	17.03	17.14	17.48		5
	1	36	17.03	17.20	17.39		5
	1	74	17.14	17.29	17.12]	5
256QAM	36	0	17.02	17.25	17.38	0-5	5
	36	18	17.10	17.28	17.46]	5
	36	37	17.13	17.14	17.38]	5
	75	0	16.99	17.22	17.41]	5

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Table 8-35 LTE Band 7 (2535.0MHz) Conducted Powers – 10MHz Bandwidth

ETE Bullu		7 (2000.0WII 12)					
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20800	21100	21400	MPR Allowed per	MPR [dB]
Wodulation	ND SIZE	IND Oliset	(2505.0 MHz)	(2505.0 MHz) (2535.0 MHz) (2565.0 MHz)		3GPP [dB]	WIFK [UD]
			(Conducted Power [dBm	1]		
	1	0	22.15	22.50	22.10		0
	1	25	22.11	22.43	22.02	0	0
	1	49	22.07	22.39	22.07		0
QPSK	25	0	21.24	21.62	21.21		1
	25	12	21.28	21.56	21.99	0-1	1
	25	25	21.17	21.52	21.20	0-1	1
	50	0	21.33	21.51	21.18		1
	1	0	21.40	21.57	21.22		1
	1	25	21.42	21.83	21.19	0-1	1
	1	49	21.44	21.68	21.23		1
16QAM	25	0	20.27	20.55	20.18		2
	25	12	20.28	20.59	20.15	0-2	2
	25	25	20.22	20.53	20.07	0-2	2
	50	0	20.20	20.56	20.18		2
	1	0	20.36	20.81	20.33		2
	1	25	20.21	20.63	20.32	0-2	2
	1	49	20.45	20.72	20.32		2
64QAM	25	0	19.25	19.63	19.19		3
	25	12	19.24	19.55	19.16	0-3	3
	25	25	19.21	19.53	19.02	0-3	3
	50	0	19.21	19.56	19.13		3
	1	0	17.24	17.34	17.42		5
	1	25	17.14	17.28	17.45		5
	1	49	17.22	17.27	17.47		5
256QAM	25	0	17.19	17.32	17.42	0-5	5
	25	12	17.18	17.27	17.41		5
	25	25	17.09	17.13	17.36		5
	50	0	17.14	17.26	17.39		5
		1					1

Table 8-36 LTE Band 7 (2535.0MHz) Conducted Powers – 5MHz Bandwidth

			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	20775	21100	21425	MPR Allowed per	MPR [dB]
Modulation	ND 0126	IND Offset	(2502.5 MHz)	(2535.0 MHz)	(2567.5 MHz)	3GPP [dB]	inii ix [ub]
				Conducted Power [dBm]		
	1	0	22.06	22.38	22.02		0
	1	12	22.18	22.42	22.11	0	0
	1	24	22.21	22.49	22.15		0
QPSK	12	0	21.20	21.50	21.14		1
	12	6	21.35	21.57	21.25	0-1	1
	12	13	21.32	21.69	21.20	0-1	1
	25	0	21.25	21.56	21.16		1
	1	0	21.32	21.78	21.37		1
	1	12	21.48	21.85	21.26	0-1	1
	1	24	21.55	21.79	21.43		1
16QAM	12	0	20.21	20.55	20.27		2
	12	6	20.43	20.58	20.26	0-2	2
	12	13	20.25	20.68	20.28	0-2	2
	25	0	20.27	20.54	20.16		2
	1	0	20.30	20.62	20.34		2
	1	12	20.44	20.83	20.38	0-2	2
	1	24	20.62	20.69	20.45]	2
64QAM	12	0	19.19	19.54	19.17		3
	12	6	19.34	19.61	19.25	0-3	3
	12	13	19.36	19.59	19.19	0-3	3
	25	0	19.27	19.50	19.13		3
	1	0	17.14	17.24	17.41		5
	1	12	17.23	17.34	17.54	1	5
	1	24	17.19	17.32	17.55		5
256QAM	12	0	17.11	17.24	17.36	0-5	5
	12	6	17.25	17.33	17.39	1	5
	12	13	17.22	17.30	17.41	7	5
	25	0	17.15	17.27	17.35	1	5

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j. LTE Band 41 - Power Class 3

Table 8-37 LTE Band 41 (2593.0MHz) Conducted Powers – 20MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Co	nducted Power [dB	m]			
	1	0	24.43	24.78	24.68	24.28	24.43		0
	1	50	24.25	24.69	24.50	24.16	24.47	0	0
	1	99	24.16	24.68	24.31	23.97	24.59		0
QPSK	50	0	23.54	23.74	23.73	23.62	23.64		1
	50	25	23.51	23.65	23.70	23.58	23.69	0-1	1
	50	50	23.46	23.56	23.59	23.49	23.71	0-1	1
	100	0	23.48	23.63	23.65	23.56	23.66		1
	1	0	23.50	23.57	23.69	23.62	23.50		1
	1	50	23.27	23.40	23.54	23.39	23.50	0-1	1
	1	99	23.25	23.37	23.36	23.23	23.60		1
16QAM	50	0	22.55	22.66	22.69	22.59	22.65		2
	50	25	22.50	22.59	22.68	22.60	22.69	0-2	2
	50	50	22.47	22.48	22.57	22.49	22.71	0-2	2
	100	0	22.51	22.57	22.67	22.57	22.68		2
	1	0	22.23	22.19	22.38	22.29	22.23		2
	1	50	22.05	22.08	22.17	22.14	22.24	0-2	2
	1	99	21.90	22.10	22.00	21.95	22.38		2
64QAM	50	0	21.61	21.70	21.72	21.68	21.72		3
	50	25	21.54	21.64	21.65	21.61	21.71	0-3	3
	50	50	21.49	21.52	21.55	21.52	21.75	0-3	3
	100	0	21.50	21.58	21.61	21.57	21.69		3
	1	0	19.34	19.32	19.43	19.38	19.32		5
	1	50	19.14	19.24	19.25	19.23	19.34	1	5
	1	99	19.05	19.22	19.07	19.04	19.47	1	5
256QAM	50	0	19.63	19.71	19.74	19.69	19.70	0-5	5
	50	25	19.54	19.65	19.69	19.60	19.74	1	5
	50	50	19.49	19.47	19.56	19.56	19.77	1	5
	100	0	19.49	19.56	19.59	19.56	19.68	1	5

Table 8-38 LTE Band 41 (2593.0MHz) Conducted Powers - 15MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Co	nducted Power [dB	im]			
	1	0	24.04	24.49	24.66	24.22	24.24		0
	1	36	23.95	24.43	24.75	24.10	24.27	0	0
	1	74	23.96	24.27	24.50	24.05	24.36		0
QPSK	36	0	23.13	23.64	23.97	23.52	23.42		1
	36	18	23.15	23.65	23.99	23.51	23.50	0-1	1
	36	37	23.15	23.52	23.94	23.40	23.45	0-1	1
	75	0	23.16	23.63	23.89	23.47	23.47		1
	1	0	23.07	23.59	23.86	23.50	23.32		1
	1	36	22.97	23.52	23.88	23.35	23.30	0-1	1
	1	74	22.98	23.40	23.87	23.22	23.41		1
16QAM	36	0	22.06	22.61	22.98	22.44	22.35		2
	36	18	22.15	22.59	22.97	22.40	22.40	0-2	2
	36	37	22.08	22.48	22.03	22.34	22.40	0-2	2
	75	0	22.16	22.63	22.96	22.45	22.45		2
	1	0	21.85	22.31	22.70	22.19	22.05		2
	1	36	21.56	22.21	22.92	22.05	22.07	0-2	2
	1	74	21.71	22.21	22.61	21.97	22.21		2
64QAM	36	0	21.19	21.66	21.99	21.48	21.41		3
	36	18	21.24	21.65	21.89	21.47	21.45	0-3	3
	36	37	21.19	21.54	21.89	21.43	21.45	0-3	3
	75	0	21.24	21.63	21.85	21.46	21.48		3
	1	0	18.93	19.43	19.96	19.27	19.48		5
	1	36	18.82	19.34	19.97	19.16	19.31		5
	1	74	18.90	19.22	19.79	19.05	19.38		5
256QAM	36	0	19.22	19.77	19.89	19.48	19.45	0-5	5
	36	18	19.17	19.66	19.78	19.46	19.43		5
	36	37	19.12	19.58	19.86	19.38	19.44		5
	75	0	19.20	19.68	19.94	19.42	19.45		5

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Table 8-39 LTE Band 41 (2593.0MHz) Conducted Powers - 10MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Co					
	1	0	23.83	24.22	24.17	23.93	24.11		0
	1	25	23.82	24.35	24.05	23.91	24.10	0	0
	1	49	23.75	24.28	23.93	23.91	24.09		0
QPSK	25	0	23.00	23.43	23.20	23.23	23.24		1
	25	12	22.99	23.47	23.23	23.23	23.26	0-1	1
	25	25	22.94	23.39	23.15	23.17	23.22	0-1	1
	50	0	23.01	23.47	23.25	23.27	23.27		1
	1	0	22.91	23.35	23.16	23.20	23.20		1
	1	25	22.86	23.32	23.18	23.12	23.17	0-1	1
	1	49	22.80	23.39	23.15	23.12	23.12		1
16QAM	25	0	22.05	22.54	22.28	22.28 22.27		2	
	25	12	22.00	22.49	22.26	22.27	22.27	0-2	2
	25	25	21.94	22.41	22.18	22.21	22.21	0-2	2
	50	0	21.98	22.47	22.20	22.25	22.26		2
	1	0	21.65	22.24	21.96	21.87	21.95		2
	1	25	21.55	22.05	21.87	21.86	21.88	0-2	2
	1	49	21.50	22.03	21.78	21.77	21.82		2
64QAM	25	0	20.98	21.45	21.25	21.23	21.24		3
	25	12	20.97	21.46	21.21	21.21	21.24	0-3	3
	25	25	20.88	21.45	21.13	21.18	21.19	0-3	3
	50	0	21.02	21.50	21.28	21.28	21.28		3
	1	0	18.80	19.24	19.05	18.93	19.04		5
	1	25	18.70	19.14	18.94	18.92	18.96		5
	1	49	18.68	19.15	18.89	18.90	18.95		5
256QAM	25	0	19.05	19.52	19.27	19.17	19.25	0-5	5
	25	12	19.02	19.49	19.02	19.23	19.24		5
	25	25	18.95	19.42	19.18	19.27	19.18		5
	50	0	19.07	19.52	19.26	19.30	19.30		5

Table 8-40 LTE Band 41 (2593.0MHz) Conducted Powers - 5MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Co	nducted Power [dB	im]			
	1	0	23.86	24.39	24.14	23.99	24.19		0
	1	12	23.86	24.40	24.14	23.99	24.27	0	0
	1	24	23.85	24.45	24.18	24.03	24.24		0
QPSK	12	0	22.97	23.45	23.24	23.31	23.31		1
	12	6	22.98	23.54	23.26	23.27	23.41	0-1	1
	12	13	22.96	23.52	23.28	23.31	23.35	0-1	1
	25	0	23.25	23.51	23.25	23.30	23.32		1
	1	0	22.90	23.47	23.28	23.18	23.21		1
	1	12	22.90	23.49	23.25	23.28	23.29	0-1	1
	1	24	22.91	23.46	23.27	23.27	23.25		1
16QAM	12	0	21.95	22.43	22.22	22.26	22.24		2
	12	6	21.89	22.45	22.25	22.22	22.34	0-2	2
	12	13	21.88	22.48	22.18	22.25	22.29	0-2	2
	25	0	22.03	22.57	22.28	22.36	22.35		2
	1	0	21.96	22.20	21.98	21.95	21.97		2
	1	12	21.63	22.25	21.95	21.97	22.03	0-2	2
	1	24	21.62	22.31	21.99	21.96	22.05		2
64QAM	12	0	20.98	21.70	21.20	21.23	21.29		3
	12	6	20.92	21.56	21.26	21.22	21.32	0-3	3
	12	13	20.91	21.48	21.21	21.32	21.33	0-3	3
	25	0	20.95	21.53	21.17	21.31	21.28		3
	1	0	18.77	19.35	19.08	19.04	19.09		5
	1	12	18.86	19.23	19.09	19.07	19.18		5
	1	24	18.79	19.23	19.04	19.11	19.14		5
256QAM	12	0	19.16	19.67	19.27	19.33	19.38	0-5	5
	12	6	19.12	19.66	19.35	19.34	19.41		5
Ī	12	13	19.13	19.63	19.35	19.35	19.42		5
1	25	0	19.08	19.56	19.26	19.32	19.35		5

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k. LTE Band 48

Table 8-41 LTE Band 48 (3625.0MHz) Conducted Powers – 20MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	55340 (3560.0 MHz)	55773 (3603.3 MHz)	56207 (3646.7 MHz)	56640 (3690.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted	Power [dBm]			
	1	0	22.62	22.96	23.00	23.03		0
	1	50	22.50	22.98	23.00	22.95	0	0
	1	99	22.60	23.09	23.12	23.02		0
QPSK	50	0	21.86	22.25	22.26	22.28		1
	50	25	21.86	22.26	22.30	22.28	0-1	1
	50	50	21.87	22.25	22.31	22.26	0-1	1
	100	0	21.84	22.24	22.30	22.27		1
	1	0	21.69	21.94	22.02	22.03		1
	1	50	21.57	21.96	22.04	22.00	0-1	1
	1	99	21.61	22.03	22.13	22.05		1
16QAM	50	0	20.82	21.24	21.22	21.28		2
	50	25	20.86	21.26	21.30	21.27	0-2	2
	50	50	20.85	21.22	21.30	21.25	0-2	2
	100	0	20.84	21.25	21.28	21.25		2
	1	0	20.43	20.65	20.74	20.81		2
	1	50	20.31	20.69	20.78	20.75	0-2	2
	1	99	20.40	20.80	20.86	20.80		2
64QAM	50	0	19.88	20.27	20.28	20.26		3
	50	25	19.90	20.31	20.34	20.30	0-3	3
	50	50	19.89	20.25	20.35	20.26	0-3	3
	100	0	19.84	20.26	20.28	20.24		3
	1	0	17.67	17.95	17.98	18.00		5
	1	50	17.53	17.98	18.00	17.93		5
	1	99	17.64	18.09	18.10	18.00		5
256QAM	50	0	17.91	18.32	18.25	18.29	0-5	5
	50	25	17.94	18.33	18.33	18.29		5
	50	50	17.92	18.29	18.31	18.28		5
	100	0	17.87	18.26	18.26	18.24		5

Table 8-42 LTE Band 48 (3625.0MHz) Conducted Powers – 15MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	(3557.5 MHz) (3602.5 MHz) (3647.5 MHz) (3692.5 MHz)		MPR Allowed per 3GPP [dB]	MPR [dB]		
				Conducted	Power [dBm]			
	1	0	22.14	22.65	22.62	22.63		0
	1	36	22.13	22.60	22.57	22.56	0	0
	1	74	22.15	22.67	22.64	22.55		0
QPSK	36	0	21.28	22.00	21.72	21.88		1
3	36	18	21.26	21.87	21.71	21.77	0-1	1
	36	37	21.20	21.77	21.91	21.69	0-1	1
	75	0	21.46	22.02	21.81	21.78		1
	1	0	21.26	21.78	21.69	21.71		1
	1	36	21.23	21.73	21.71	21.72	0-1	1
16QAM	1	74	21.22	21.78	21.69	21.71		1
	36	0	20.59	20.96	20.77	20.83		2
	36	18	20.59	20.93	20.84	20.64	0-2	2
	36	37	20.61	20.93	20.60	20.64	0-2	2
	75	0	20.69	20.90	20.89	20.78		2
	1	0	20.10	20.73	20.59	20.50		2
	1	36	20.08	20.70	20.51	20.40	0-2	2
	1	74	20.17	20.80	20.66	20.50		2
64QAM	36	0	19.60	20.26	19.81	19.68		3
	36	18	19.71	20.25	19.71	19.86	0-3	3
	36	37	19.63	20.20	19.71	19.68	0-3	3
	75	0	19.56	20.26	19.90	19.99		3
	1	0	17.10	17.43	17.83	17.96		5
	1	36	17.12	17.53	17.89	17.93		5
	1	74	17.19	17.71	17.95	17.85		5
256QAM	36	0	17.25	17.89	18.17	18.05	0-5	5
	36	18	17.47	17.75	17.95	18.00		5
	36	37	17.50	17.54	18.21	18.21		5
	75	0	17.48	17.65	18.22	18.29		5

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Table 8-43 LTE Band 48 (3625.0MHz) Conducted Powers – 10MHz Bandwidth

			OMITE Danawiath					
			Low Channel	Low-Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	55290 (3555.0 MHz)	55773 (3601.7 MHz)	56207 (3648.3 MHz)	56690 (3695.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted	Power [dBm]			
	1	0	21.93	22.31	22.49	22.53		0
	1	25	22.06	22.50	22.50	22.65	0	0
QPSK	1	49	22.07	22.60	22.52	22.62		0
	25	0	21.33	21.49	21.64	21.83		1
	25	12	21.36	21.60	21.68	21.90	0-1	1
	25	25	21.24	21.66	21.70	21.89	0-1	1
	50	0	21.30	21.65	21.74	21.89		1
	1	0	21.02	21.46	21.55	21.60		1
	1	25	21.06	21.56	21.66	21.73	0-1	1
16QAM	1	49	21.18	21.47	21.58	21.70		1
	25	0	19.96	20.43	20.57	20.81		2
	25	12	20.26	20.55	20.62	20.84	0-2	2
	25	25	20.29	20.48	20.59	20.83	0-2	2
	50	0	20.22	20.65	20.70	20.84		2
	1	0	19.79	20.31	20.23	20.34		2
	1	25	19.82	20.24	20.40	20.46	0-2	2
	1	49	19.94	20.39	20.33	20.44		2
64QAM	25	0	19.09	19.61	19.70	19.72		3
	25	12	19.12	19.69	19.84	19.81	0-3	3
	25	25	19.27	19.65	19.72	19.85	0-3	3
	50	0	19.38	19.69	20.16	19.89		3
	1	0	17.39	17.38	17.66	17.57		5
	1	25	17.36	17.58	17.77	17.96		5
	1	49	17.51	17.50	17.89	17.90		5
256QAM	25	0	17.55	17.65	18.18	18.04	0-5	5
	25	12	17.52	17.80	17.93	18.12		5
	25	25	17.60	17.75	17.89	18.13		5
	50	0	17.59	17.69	17.93	18.15		5

Table 8-44 LTE Band 48 (3625.0MHz) Conducted Powers – 5MHz Bandwidth

			Low Channel	Low-Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	55265 (3552.5 MHz)	55773 (3600.8 MHz)	56207 (3649.2 MHz)	56715 (3697.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted	Power [dBm]			
	1	0	21.91	22.58	22.70	22.73		0
	1	12	22.00	22.64	22.74	22.84	0	0
	1	24	22.03	22.66	22.78	22.72		0
QPSK	12	0	21.12	21.80	21.91	22.04		1
	12	6	21.25	21.86	21.91	21.95	0-1	1
	12	13	21.24	21.86	21.83	22.03	0-1	1
	25	0	21.25	21.90	21.89	21.95		1
	1	0	21.05	21.71	21.66	21.88		1
	1	12	21.14	21.77	21.72	21.95	0-1	1
	1	24	21.17	21.77	21.65	21.88		1
16QAM	12	0	20.11	20.77	20.86	20.92		2
	12	6	20.16	20.80	20.76	20.84	0-2	2
	12	13	20.15	20.81	20.87	20.84	0-2	2
	25	0	20.20	20.88	20.85	20.93		2
	1	0	20.01	20.31	20.31	20.42		2
	1	12	20.15	20.42	20.47	20.56	0-2	2
	1	24	20.16	20.45	20.60	20.68		2
64QAM	12	0	19.47	19.80	19.77	20.06		3
	12	6	19.53	19.89	19.94	19.85	0-3	3
	12	13	19.54	19.90	19.77	19.87	0-3	3
	25	0	19.47	19.85	19.98	20.07		3
	1	0	16.97	17.73	17.61	17.74		5
	1	12	17.02	17.81	17.80	18.10	I	5
	1	24	17.02	17.77	17.99	17.81		5
256QAM	12	0	17.24	18.02	18.24	18.04	0-5	5
	12	6	17.31	18.08	17.94	18.05	1	5
	12	13	17.30	18.07	18.03	18.04		5
	25	0	17.24	17.99	17.98	18.00		5

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I. LTE Uplink Carrier Aggregation

Table 8-45 LTE FDD Uplink Two Component Carrier Aggregation Conducted Powers

		PCC					SCC								
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL) Channel	PCC (UL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL) Channel	SCC (UL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	LTE Tx.Power with UL CA Enabled (dBm)
CA_5B	LTE B5	10	20525	836.5	16QAM	1	0	LTE B5	5	20453	829.3	16QAM	1	24	23.98
CA_66B	LTE B66	10	132322	1745.0	16QAM	1	0	LTE B66	10	132223	1735.1	16QAM	1	49	22.52
CA_66C	LTE B66	20	132322	1745.0	16QAM	1	0	LTE B66	20	132124	1725.2	16qAM	1	99	22.72

VIII. WIFI Conducted Powers (SISO/MIMO)

Table 8-46 IEEE 802.11b/α/n/ax (2.4GHz, SISO) Reduced Average RF Power¹

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2.4GHz Conducted Power [dBm]								
			IEEE Transmission Mode					
Freq [MHz]	Channel	802.11b	802.11g	802.11n	802.11ax SU			
		Average	Average	Average	Average			
2412	1	16.77	16.63	16.61	16.71			
2437	6	16.92	16.54	16.52	16.33			
2462	11	16.83	16.73	16.94	16.79			

Table 8-47 IEEE 802.11g/n/ax (2.4GHz, MIMO) Reduced Average RF Power¹

2.4GHz Conducted Power [dBm]								
	Mode							
Freq [MHz]	Channel	802.11g	802.11n	802.11ax SU				
		Average	Average	Average				
2412	1	19.65	19.56	19.72				
2437	6	19.55	19.45	19.50				
2462	11	19.85	19.89	19.79				

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-48 IEEE 802.11a/n/ac/ax (5GHz, 20MHz BW, SISO) Reduced Average RF Power¹

IEEE 002.11a	,		ducted Power		30 10 1 0000
			IEEE Transm	nission Mode	
Freq [MHz]	Channel	802.11a	802.11n	802.11ac	802.11ax SU
		Average	Average	Average	Average
5180	36	13.83	13.66	13.68	13.41
5200	40	13.86	13.68	13.77	13.48
5220	44	13.67	13.67	13.72	13.44
5240	48	13.60	13.75	13.64	13.42
5260	52	13.88	13.89	13.91	13.86
5280	56	13.83	13.92	13.93	13.81
5300	60	13.93	13.90	13.98	13.81
5320	64	13.81	13.78	13.82	13.65
5500	100	13.41	13.86	13.79	13.73
5600	120	13.80	13.78	13.75	13.60
5620	124	13.71	13.73	13.75	13.45
5720	144	13.51	13.77	13.73	13.69
5745	149	13.45	13.63	13.43	13.88
5785	157	13.57	13.48	13.50	13.75
5825	165	13.85	13.77	13.80	13.59

Table 8-49 IEEE 802.11a/n/ac/ax (5GHz, 20MHz BW, MIMO) Reduced Average RF Power¹

	5GHz (20MHz) Conducted Power [dBm]									
			IEEE Transm	nission Mode						
Freq [MHz]	Channel	802.11a	802.11n	802.11ac	802.11ax SU					
		Average	Average	Average	Average					
5180	36	16.78	16.67	16.71	16.53					
5200	40	16.75	16.72	16.80	16.73					
5220	44	16.67	16.71	16.75	16.51					
5240	48	16.67	16.79	16.68	16.55					
5260	52	16.68	16.70	16.74	16.86					
5280	56	16.69	16.75	16.79	16.80					
5300	60	16.75	16.78	16.81	16.90					
5320	64	16.68	16.88	16.66	16.80					
5500	100	16.60	16.77	16.72	16.82					
5600	120	16.71	16.87	16.70	16.71					
5620	124	16.62	16.83	16.82	16.62					
5720	144	16.55	16.76	16.66	16.83					
5745	149	16.71	16.78	16.69	16.91					
5785	157	16.75	16.70	16.75	16.82					
5825	165	16.77	16.71	16.71	16.76					

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-50 IEEE 802.11n/ac/ax (5GHz, 40MHz BW, SISO) Reduced Average RF Power¹

5GHz (40MHz) Conducted Power [dBm]						
		IEEE '	Transmission	Mode		
Freq [MHz]	Channel	802.11n	802.11ac	802.11ax SU		
		Average	Average	Average		
5190	38	13.70	13.82	13.57		
5230	46	13.86	13.92	13.59		
5270	54	13.74	13.66	13.84		
5310	62	13.94	13.82	13.72		
5510	102	13.80	13.78	13.92		
5590	118	13.87	13.82	13.78		
5630	126	13.89	13.85	13.72		
5710	142	13.64	13.60	13.80		
5755	151	13.59	13.49	13.87		
5795	159	13.86	13.79	13.58		

Table 8-51 IEEE 802.11n/ac/ax (5GHz, 40MHz BW, MIMO) Reduced Average RF Power¹

5GHz (40MHz) Conducted Power [dBm]						
		IEEE Transmission Mode				
Freq [MHz]	Channel	802.11n	802.11ac	802.11ax SU		
		Average	Average	Average		
5190	38	16.73	16.74	16.72		
5230	46	16.76	16.79	16.79		
5270	54	16.82	16.80	16.80		
5310	62	16.93	16.89	16.69		
5510	102	16.76	16.74	16.93		
5590	118	16.87	16.84	16.71		
5630	126	16.79	16.78	16.70		
5710	142	16.63	16.58	16.82		
5755	151	16.77	16.73	16.83		
5795	159	16.79	16.74	16.78		

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-52 IEEE 802.11ac/ax (5GHz, 80MHz BW, SISO) Reduced Average RF Power¹

5GHz	z (80MHz) Cond	ducted Power	dBm]	
From FRALL-1	Chamal	IEEE Transr	nission Mode	
Freq [MHz]	Channel	802.11ac	802.11ax SU	
		Average	Average	
5210	42	12.51	12.71	
5290	58	12.68	12.73	
5530	106	13.42	12.89	
5610	122	13.72	12.56	
5690	138	13.85	12.94	
5775	155	13.50	12.38	

Table 8-53 IEEE 802.11ac/ax (5GHz, 80MHz BW, MIMO) Reduced Average RF Power¹

5GHz (80MHz) Conducted Power [dBm]						
Erea (MU=1	Channel	IEEE Transı	mission Mode			
Freq [MHz]	Channel	802.11ac	802.11ac SU			
		Average	Average			
5210	42	15.64	15.71			
5290	58	15.74	15.84			
5530	106	16.05	15.71			
5610	122	16.35	15.72			
5690	138	16.39	15.96			
5775	155	16.13	15.42			

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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IX. WIFI Conducted Powers for IEEE 802.11ax RU (SISO/MIMO)

Table 8-54 IEEE 802.11ax (2.4GHz, RU, SISO) Maximum Average RF Power¹

IEEE 802.11	ax (2.40nz, K	U, SISU) IVIAX	illiulli Averay	e Kr Power
RU Index	Tones	Ch. 1	Ch. 6	Ch. 11
0	26	13.61	13.59	13.35
4	26	13.67	13.52	13.99
8	26	13.72	13.96	13.67
37	52	14.69	14.69	14.95
38	52	14.86	14.98	14.82
40	52	14.52	14.90	14.59
53	106	15.82	15.89	15.63
54	106	15.98	15.52	15.37
61	242	15.79	16.60	15.39

Table 8-55 IEEE 802.11ax (2.4GHz, RU, MIMO) Maximum Average RF Power¹

RU Index	Tones	Ch. 1	Ch. 6	Ch. 11
0	26	13.73	13.73	13.75
4	26	13.94	13.78	13.87
8	26	13.99	13.69	13.49
37	52	14.70	14.74	14.49
38	52	14.98	14.68	14.96
40	52	14.85	14.80	14.80
53	106	15.45	15.68	15.60
54	106	15.62	15.99	15.43
61	242	15.71	16.18	15.36

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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Table 8-56 IEEE 802.11ax (5GHz, 20MHz BW, RU, SISO) Maximum Average RF Power¹

RU Index	Tones		UNII 1		RU Index	Tonnes		UNII 2A	
		Ch. 36	Ch. 40	Ch. 48			Ch. 52	Ch. 56	Ch. 64
0	26	10.56	10.54	10.54	0	26	10.41	10.95	10.50
4	26	10.87	10.80	10.94	4	26	10.65	10.66	10.71
8	26	10.73	10.68	10.78	8	26	10.98	10.54	10.50
37	52	12.75	12.70	12.65	37	52	12.51	12.57	12.60
38	52	12.83	12.89	12.88	38	52	12.70	12.75	12.72
40	52	12.81	12.82	12.86	40	52	12.57	12.58	12.57
53	106	14.54	14.65	14.61	53	106	14.50	14.58	14.57
54	106	14.75	14.73	14.68	54	106	14.56	14.51	14.53
61	242	15.73	15.63	15.65	61	242	15.52	15.51	15.56
RU Index	Tones		UNII 2C		RU Index	Tones		UNII 3	
RU Index	Tones	Ch. 100	UNII 2C Ch. 120	Ch. 144	RU Index	Tones	Ch. 149	UNII 3 Ch. 157	Ch. 165
RU Index	Tones 26	Ch. 100 10.95		Ch. 144 10.67	RU Index	Tones 26	Ch. 149 10.93		Ch. 165 10.50
			Ch. 120					Ch. 157	
0	26	10.95	Ch. 120 10.77	10.67	0	26	10.93	Ch. 157 10.83	10.50
0 4	26 26	10.95 10.64	Ch. 120 10.77 10.98	10.67 10.96	0 4	26 26	10.93 10.65	Ch. 157 10.83 10.70	10.50 10.90
0 4 8	26 26 26	10.95 10.64 10.94	Ch. 120 10.77 10.98 10.76	10.67 10.96 10.76	0 4 8	26 26 26	10.93 10.65 10.70	Ch. 157 10.83 10.70 10.77	10.50 10.90 10.58
0 4 8 37	26 26 26 52	10.95 10.64 10.94 12.82	Ch. 120 10.77 10.98 10.76 12.68	10.67 10.96 10.76 12.72	0 4 8 37	26 26 26 52	10.93 10.65 10.70 12.96	Ch. 157 10.83 10.70 10.77 12.82	10.50 10.90 10.58 12.57
0 4 8 37 38	26 26 26 26 52 52	10.95 10.64 10.94 12.82 12.90	Ch. 120 10.77 10.98 10.76 12.68 12.81	10.67 10.96 10.76 12.72 12.88	0 4 8 37 38	26 26 26 26 52 52	10.93 10.65 10.70 12.96 12.63	Ch. 157 10.83 10.70 10.77 12.82 12.99	10.50 10.90 10.58 12.57 12.75
0 4 8 37 38 40	26 26 26 52 52 52	10.95 10.64 10.94 12.82 12.90 12.86	Ch. 120 10.77 10.98 10.76 12.68 12.81 12.64	10.67 10.96 10.76 12.72 12.88 12.70	0 4 8 37 38 40	26 26 26 52 52 52	10.93 10.65 10.70 12.96 12.63 12.75	Ch. 157 10.83 10.70 10.77 12.82 12.99 12.77	10.50 10.90 10.58 12.57 12.75 12.55

Table 8-57 IEEE 802.11ax (5GHz. 20MHz BW. RU. MIMO) Maximum Average RF Power¹

		1000	_, _ •	 ;	, IVIIIVIO) IV		<u> </u>		
RU Index	Tones		UNII 1		RU Index	Tones		UNII 2A	
KU IIIQEX	Tones	Ch. 36	Ch. 40	Ch. 48	INO IIIUEX	Tones	Ch. 52	Ch. 56	Ch. 64
0	26	10.59	10.63	10.77	0	26	10.70	10.83	10.82
4	26	10.93	10.94	10.97	4	26	10.95	10.92	10.99
8	26	10.74	10.66	10.80	8	26	10.71	10.84	10.70
37	52	12.69	12.75	12.86	37	52	12.81	12.88	12.81
38	52	12.96	12.93	12.90	38	52	12.99	12.52	12.95
40	52	12.84	12.81	12.87	40	52	12.87	12.89	12.87
53	106	14.80	14.85	14.85	53	106	14.88	14.94	14.81
54	106	14.82	14.90	14.88	54	106	14.89	14.98	14.90
61	242	15.84	15.80	15.85	61	242	15.95	15.87	15.97
BII Indov	Tonco		UNII 2C		DII Indov	Tonco		UNII 3	
RU Index	Tones	Ch. 100	UNII 2C Ch. 120	Ch. 144	RU Index	Tones	Ch. 149	UNII 3 Ch. 157	Ch. 165
RU Index	Tones 26	Ch. 100 10.67		Ch. 144 10.64	RU Index	Tones 26	Ch. 149 10.74		Ch. 165 10.68
			Ch. 120					Ch. 157	
0	26	10.67	Ch. 120 10.98	10.64	0	26	10.74	Ch. 157 10.91	10.68
0 4	26 26	10.67 10.93	Ch. 120 10.98 10.55	10.64 10.79	0 4	26 26	10.74 10.83	Ch. 157 10.91 10.81	10.68 10.52
0 4 8	26 26 26	10.67 10.93 10.60	Ch. 120 10.98 10.55 10.87	10.64 10.79 10.97	0 4 8	26 26 26	10.74 10.83 10.96	Ch. 157 10.91 10.81 10.83	10.68 10.52 10.58
0 4 8 37	26 26 26 52	10.67 10.93 10.60 12.72	Ch. 120 10.98 10.55 10.87 12.99	10.64 10.79 10.97 12.64	0 4 8 37	26 26 26 52	10.74 10.83 10.96 12.62	Ch. 157 10.91 10.81 10.83 12.89	10.68 10.52 10.58 12.68
0 4 8 37 38	26 26 26 26 52 52	10.67 10.93 10.60 12.72 12.85	10.98 10.55 10.87 12.99 12.61	10.64 10.79 10.97 12.64 12.76	0 4 8 37 38	26 26 26 26 52 52	10.74 10.83 10.96 12.62 12.68	Ch. 157 10.91 10.81 10.83 12.89 12.60	10.68 10.52 10.58 12.68 12.89
0 4 8 37 38 40	26 26 26 52 52 52	10.67 10.93 10.60 12.72 12.85 12.64	10.98 10.55 10.87 12.99 12.61 12.88	10.64 10.79 10.97 12.64 12.76 12.52	0 4 8 37 38 40	26 26 26 52 52 52	10.74 10.83 10.96 12.62 12.68 12.92	Ch. 157 10.91 10.81 10.83 12.89 12.60 12.76	10.68 10.52 10.58 12.68 12.89 12.63

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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Table 8-58 IEEE 802.11ax (5GHz, 40MHz BW, RU, SISO) Maximum Average RF Power¹

1222 002111031 (00112, 1011112 211) 110				z, cice, maximum z troi ago i a i circi				
RU Index	Tones	UN	III 1	RU Index	Tonnes	UNI	I 2A	
RU Index	Tones	Ch. 38	Ch. 46	RU Index	Tonnes	Ch. 54	Ch. 62	
0	26	10.52	10.48	0	26	10.92	10.83	
8	26	10.88	10.80	8	26	10.91	10.92	
17	26	10.63	10.58	17	26	10.95	10.92	
37	52	11.86	11.74	37	52	11.85	11.74	
40	52	11.81	11.72	40	52	11.98	11.98	
44	52	11.83	11.87	44	52	11.85	11.60	
53	106	12.97	12.92	53	106	12.99	12.98	
54	106	12.80	12.82	54	106	12.99	12.88	
56	106	12.96	12.95	56	106	12.98	12.78	
61	242	13.98	13.89	61	242	13.60	13.56	
62	242	13.87	13.74	62	242	13.68	13.92	
65	484	13.55	13.60	65	484	13.90	13.76	

Dilladey	Tonnoo		UNII 2C		DLLInday	Tonos	UN	III 3
RU Index	Tonnes	Ch. 102	Ch. 118	Ch. 142	RU Index	Tones	Ch. 151	Ch. 159
0	26	10.88	10.60	10.71	0	26	10.92	10.83
8	26	10.88	10.60	10.85	8	26	10.91	10.83
17	26	10.99	10.98	10.65	17	26	10.80	10.87
37	52	11.97	11.83	11.96	37	52	11.83	11.99
40	52	11.98	11.52	11.81	40	52	11.83	11.68
44	52	11.58	11.70	11.82	44	52	11.72	11.94
53	106	12.76	12.94	12.62	53	106	12.97	12.89
54	106	12.76	12.99	12.78	54	106	12.93	12.78
56	106	12.75	12.88	12.98	56	106	12.81	12.80
61	242	13.87	13.99	13.80	61	242	13.98	13.75
62	242	13.99	13.98	13.58	62	242	13.71	13.81
65	484	13.68	13.86	13.98	65	484	13.81	13.97

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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Table 8-59 IEEE 802.11ax (5GHz, 40MHz BW, RU, MIMO) Maximum Average RF Power¹

- 		,		,			
RU Index	Tones	UNII 1		RU Index	Tones	UNI	I 2A
KU IIIUEX	Tories	Ch. 38	Ch. 46	KU IIIUEX	Tones	Ch. 54	Ch. 62
0	26	10.57	10.52	0	26	10.60	10.66
8	26	10.72	10.68	8	26	10.53	10.64
17	26	10.74	10.64	17	26	10.59	10.55
37	52	11.88	11.86	37	52	11.81	11.95
40	52	11.80	11.69	40	52	11.67	11.71
44	52	11.95	11.51	44	52	11.97	11.84
53	106	12.62	12.62	53	106	12.62	12.63
54	106	12.76	12.78	54	106	12.67	12.76
56	106	12.69	12.81	56	106	12.65	12.62
61	242	13.88	13.91	61	242	13.88	13.93
62	242	13.93	13.92	62	242	13.94	13.93
65	484	13.71	13.73	65	484	13.67	13.67

DILladev	Tonos		UNII 2C		DILInday	Tonco	UN	II 3
RU Index	Tones	Ch. 102	Ch. 118	Ch. 142	RU Index	Tones	Ch. 151	Ch. 159
0	26	10.67	10.94	10.97	0	26	10.97	10.97
8	26	10.53	10.69	10.89	8	26	10.98	10.99
17	26	10.61	10.81	10.90	17	26	10.93	10.78
37	52	11.77	11.99	11.67	37	52	11.75	11.64
40	52	11.60	11.77	11.94	40	52	11.94	11.99
44	52	11.84	11.95	11.60	44	52	11.65	11.51
53	106	12.58	12.73	12.99	53	106	12.91	12.97
54	106	12.58	12.71	12.96	54	106	12.85	12.76
56	106	12.57	12.80	12.95	56	106	12.77	12.91
61	242	13.88	13.60	13.65	61	242	13.61	13.89
62	242	13.94	13.60	13.61	62	242	13.64	13.86
65	484	13.97	13.62	13.95	65	484	13.85	13.63

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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Table 8-60 IEEE 802.11ax (5GHz, 80MHz BW, RU, SISO) Maximum Average RF Power¹

. w.x. 100	_,		e, elee, maximam , treragi				
RU Index	Tones	UNII 1	RU Index	Tonnes	UNII 2A		
NO IIIdex	Tories	Ch. 42	NO IIIdex	Tornes	Ch. 58		
0	26	10.56	0	26	10.77		
17	26	10.65	17	26	10.98		
36	26	10.57	36	26	10.85		
37	52	10.68	37	52	10.91		
44	52	10.60	44	52	10.50		
52	52	10.69	52	52	10.99		
53	106	11.93	53	106	11.71		
56	106	11.83	56	106	11.98		
60	106	11.80	60	106	11.76		
61	242	12.85	61	242	12.96		
62	242	12.93	62	242	12.73		
64	242	12.68	64	242	12.98		
65	484	12.98	65	484	12.81		
66	484	12.98	66	484	12.77		
67	996	12.98	67	996	12.79		

Dillades	Tannas		UNII 2C		RU Index	Tonce	UNII 3
RU Index	Tonnes	Ch. 106	Ch. 122	Ch. 138	RU Index	Tones	Ch. 155
0	26	10.85	10.99	10.83	0	26	10.68
17	26	10.84	10.89	10.74	17	26	10.76
36	26	10.54	10.70	10.98	36	26	10.53
37	52	10.98	10.75	10.67	37	52	10.88
44	52	10.82	10.94	10.82	44	52	10.83
52	52	10.90	10.89	10.70	52	52	10.72
53	106	11.65	11.84	11.67	53	106	11.65
56	106	11.82	11.98	11.79	56	106	11.80
60	106	11.89	11.48	11.82	60	106	11.97
61	242	12.85	12.57	12.80	61	242	12.88
62	242	12.83	12.98	12.84	62	242	12.90
64	242	12.71	12.91	12.98	64	242	12.56
65	484	12.87	12.71	12.56	65	484	12.57
66	484	12.99	12.69	12.99	66	484	12.55
67	996	12.48	12.74	12.95	67	996	12.99

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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Table 8-61 IEEE 802.11ax (5GHz, 80MHz BW, RU, MIMO) Maximum Average RF Power¹

ust (0 0 1 1 =) 0 0 1 1 1 1 1 2 1 1 3 1 1 0			,			
RU Index	Tones	UNII 1	RU Index	Tones	UNII 2A	
RU IIIuex	Tones	Ch. 42	RU Illuex	Tones	Ch. 58	
0	26	10.99	0	26	10.90	
18	26	10.58	18	26	10.99	
36	26	10.60	36	26	10.94	
37	52	10.67	37	52	10.59	
44	52	10.65	44	52	10.59	
52	52	10.65	52	52	10.63	
53	106	11.86	53	106	11.85	
56	106	11.81	56	106	11.62	
60	106	11.46	60	106	11.86	
61	242	12.71	61	242	12.69	
62	242	12.94	62	242	12.90	
64	242	12.83	64	242	12.67	
65	484	12.97	65	484	12.94	
66	484	12.68	66	484	12.98	
67	996	12.99	67	996	12.78	

Dilladay	T		UNII 2C		Dilledon	T	UNII 3
RU Index	Tones	Ch. 106	Ch. 122	Ch. 138	RU Index	Tones	Ch. 155
0	26	10.57	10.86	10.80	0	26	10.87
18	26	10.97	10.62	10.77	18	26	10.90
36	26	10.89	10.60	10.66	36	26	10.64
37	52	10.71	10.99	10.87	37	52	10.62
44	52	10.98	10.58	10.91	44	52	10.79
52	52	10.99	10.65	10.89	52	52	10.84
53	106	11.80	11.60	11.82	53	106	11.73
56	106	11.63	11.77	11.94	56	106	11.84
60	106	11.69	11.88	11.98	60	106	11.89
61	242	12.56	12.81	12.54	61	242	12.76
62	242	12.73	12.91	12.65	62	242	12.93
64	242	12.99	12.72	12.98	64	242	12.76
65	484	12.89	12.66	12.81	65	484	12.70
66	484	12.96	12.63	12.71	66	484	12.57
67	996	12.65	12.79	12.48	67	996	12.88

¹ Note: While this device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios, maximum conducted powers were used as a conservative measure in Section 8.IX.

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X. WIFI Conducted Powers for Operations with Simultaneous 2.4GHz and 5GHz

Table 8-62 IEEE 802.11b/g/n/ac/ax (2.4GHz, Ant1) Reduced Average RF Power¹

2.4GHz Conducted Power [dBm]					
		IEEE Transmission Mode			
Freq [MHz]	Channel	802.11b	802.11g	802.11n	802.11ax
		Average	Average	Average	Average
2412	1	13.81	13.79	13.79	13.98
2437	6	13.79	13.60	13.99	13.92
2462	11	13.70	13.98	13.94	13.49

Table 8-63 IEEE 802.11b/g/n/ac/ax (2.4GHz, Ant2) Reduced Average RF Power¹

	==== oo=:::::::::::::::::::::::::::::::				
2.4GHz Conducted Power [dBm]					
		IEEE Transmission Mode			
Freq [MHz]	Channel	802.11b	802.11g	802.11n	802.11ax
		Average	Average	Average	Average
2412	1	13.89	13.57	13.43	13.81
2437	6	13.96	13.99	13.91	13.97
2462	11	13.97	13.80	13.63	13.82

Table 8-64 IEEE 802.11a/n/ac/ax (5GHz, 20MHz BW, Ant1) Reduced Average RF Power¹

	5GHz (20MHz) Conducted Power [dBm]					
			IEEE Transm	nission Mode		
Freq [MHz]	Channel	802.11a	802.11n	802.11ac	802.11ax SU	
		Average	Average	Average	Average	
5180	36	13.83	13.66	13.68	13.41	
5200	40	13.86	13.68	13.77	13.48	
5220	44	13.67	13.67	13.72	13.44	
5240	48	13.60	13.75	13.64	13.42	
5260	52	13.88	13.89	13.91	13.86	
5280	56	13.83	13.92	13.93	13.81	
5300	60	13.93	13.90	13.98	13.81	
5320	64	13.81	13.78	13.82	13.65	
5500	100	13.41	13.86	13.79	13.73	
5600	120	13.80	13.78	13.75	13.60	
5620	124	13.71	13.73	13.75	13.45	
5720	144	13.51	13.77	13.73	13.69	
5745	149	13.45	13.63	13.43	13.88	
5785	157	13.57	13.48	13.50	13.75	
5825	165	13.85	13.77	13.80	13.59	

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-65 IEEE 802.11a/n/ac/ax (5GHz, 20MHz BW, Ant2) Reduced Average RF Power¹

5GHz (20MHz) Conducted Power [dBm]					
			IEEE Transm	nission Mode	
Freq [MHz]	Channel	802.11a	802.11n	802.11ac	802.11ac SU
		Average	Average	Average	Average
5180	36	13.71	13.65	13.72	13.63
5200	40	13.62	13.74	13.80	13.95
5220	44	13.64	13.72	13.75	13.55
5240	48	13.72	13.80	13.69	13.65
5260	52	13.45	13.48	13.54	13.84
5280	56	13.53	13.55	13.62	13.77
5300	60	13.54	13.63	13.62	13.96
5320	64	13.52	13.95	13.47	13.92
5500	100	13.76	13.66	13.63	13.89
5600	120	13.59	13.93	13.63	13.80
5620	124	13.51	13.91	13.87	13.77
5720	144	13.57	13.73	13.56	13.94
5745	149	13.94	13.91	13.92	13.91
5785	157	13.90	13.89	13.96	13.87
5825	165	13.66	13.63	13.59	13.90

Table 8-66 IEEE 802.11n/ac/ax (5GHz, 40MHz BW, Ant1) Reduced Average RF Power¹

	5GHz (40MHz) Conducted Power [dBm]					
		IEEE '	IEEE Transmission Mode			
Freq [MHz]	Channel	802.11n	802.11ac	802.11ax SU		
		Average	Average	Average		
5190	38	13.70	13.82	13.57		
5230	46	13.86	13.92	13.59		
5270	54	13.74	13.66	13.84		
5310	62	13.94	13.82	13.72		
5510	102	13.80	13.78	13.92		
5590	118	13.87	13.82	13.78		
5630	126	13.89	13.85	13.72		
5710	142	13.64	13.60	13.80		
5755	151	13.59	13.49	13.87		
5795	159	13.86	13.79	13.58		

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-67 IEEE 802.11n/ac/ax (5GHz, 40MHz BW, Ant2) Reduced Average RF Power¹

	5GHz (40MHz) Conducted Power [dBm]					
		IEEE Transmission Mode				
Freq [MHz]	Channel	802.11n	802.11ac	802.11ac SU		
		Average	Average	Average		
5190	38	13.73	13.63	13.85		
5230	46	13.63	13.63	13.96		
5270	54	13.88	13.91	13.73		
5310	62	13.89	13.93	13.63		
5510	102	13.70	13.67	13.92		
5590	118	13.85	13.84	13.62		
5630	126	13.67	13.68	13.65		
5710	142	13.60	13.54	13.82		
5755	151	13.93	13.94	13.77		
5795	159	13.70	13.67	13.96		

Table 8-68 IEEE 802.11ac/ax (5GHz, 80MHz BW, Ant1) Reduced Average RF Power¹

5GHz (80MHz) Conducted Power [dBm]				
Free [Mile]		IEEE Transmission Mode		
Freq [MHz]	Channel	802.11ac	802.11ax SU	
		Average	Average	
5210	42	12.51	12.71	
5290	58	12.68	12.73	
5530	106	13.42	12.89	
5610	122	13.72	12.56	
5690	138	13.85	12.94	
5775	155	13.50	12.38	

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-69 IEEE 802.11ac/ax (5GHz, 80MHz BW, Ant2) Reduced Average RF Power¹

5GHz (80MHz) Conducted Power [dBm]					
Free [Mile]	Channel	IEEE Transmission Mode	IEEE Transmission Mode		
Freq [MHz]	Channel	802.11ac	802.11ax SU		
		Average	Average		
5210	42	12.75	12.69		
5290	58	12.77	12.93		
5530	106	13.71	12.50		
5610	122	13.95	12.85		
5690	138	13.72	12.96		
5775	155	13.65	12.43		

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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9. JUSTIFICATION OF HELD TO EAR MODES TESTED

I. Analysis of RF Air Interface Technologies

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst-case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst-case MIF plus the worst-case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

II. Individual Mode Evaluations

Table 9-1

Max Power + MIF calculations for Low Power Exemptions

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
CDMA - Full Frame Rate (SO55/RC1)	24.65	-19.04	5.61	No
CDMA - 1/8 th Frame Rate (SO3/RC1)	15.57*	3.08	18.65	Yes
CDMA - EvDO	24.51	-17.85	6.66	No
GSM850	23.44*	3.50	26.94	Yes
GSM1900	20.51*	3.54	24.05	Yes
EDGE850	17.60*	3.77	21.37	Yes***
EDGE1900	16.68*	3.74	20.42	Yes***
UMTS - RMC	24.93	-22.90	2.03	No
UMTS - AMR	24.94	-13.39	11.55	No
HSPA	24.02	-23.02	1.00	No
LTE - FDD	25.28	-9.54	15.74	No
LTE FDD - Uplink Carrier Aggregation	23.98	-9.40	14.58	No
LTE Band 41 - TDD (PC3)	18.09*	1.53	19.62	Yes
LTE Band 48	20.22*	-2.34	17.88	Yes
2.4GHz WIFI	19.89	-4.71	15.18	No
5GHz WIFI	16.93	-4.59	12.34	No
Simultaneous 2.4GHz and 5GHz WIFI Operations	20.00**	-4.67	15.33	No

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- * Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.
- ** Note: This value is calculated as the linear sum of the worst-case power for each band and antenna combination while in simultaneous 2.4GHz and 5GHz operation. This calculation is conservative and for use in this investigation only.
- *** Note: EDGE data modes were considered but not tested as GSM voice modes were found to be the worst-case modes for the GSM air interface.

III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for CDMA 1/8th Frame Rate and GSM voice modes as well as LTE TDD (Power Class 3) data modes. All other air interfaces are exempt.

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10. LTE TDD UPLINK-DOWNLINK CONFIGURATION

I. Uplink-Downlink Configuration Additional Testing

Additional testing was performed on each supported power class for LTE TDD to determine the worst-case Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length $T_f = 307200 \cdot T_s = 10$ ms, where T_s is a number of time units equal to 1/(15000 x 2048) seconds. Additionally, each radio frame consists of 10 subframes, each of length 30720 · T_s = 1 ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192 · Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

> **Table 10-1** Uplink-Downlink Configurations for Type 2 Frame Structures

					· <i>J</i> -							
Uplink-downlink configuration	Downlink-to-Uplink Switch-point periodicity		Subframe number									Calculated Transmission
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	U	U	U	D	S	U	U	U	61.4%
1	5 ms	D	S	U	U	D	D	S	U	U	D	41.4%
2	5 ms	D	S	U	D	D	D	S	U	D	D	21.4%
3	10 ms	D	S	U	U	U	D	D	D	D	D	30.7%
4	10 ms	D	S	U	U	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

II. Power Class 3 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emission was used for full testing. See Tables 10-2 and 10-3 below for results. The configurations determined in the results from Tables 10-2 and 10-3 were used to measure the MIF values in Tables 7-6 and 7-7.

> **Table 10-2** LTE TDD B41 Power Class 3 UL-DL Configuration Results

Mode / Band	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	0	16QAM	1	0	Acoustic	11.76	21.41	-3.23	18.18	35.00	-16.82	M4	none
	20	40620	1	16QAM	1	0	Acoustic	9.51	19.56	-1.55	18.01	35.00	-16.99	M4	none
	20	40620	2	16QAM	1	0	Acoustic	7.70	17.73	1.47	19.20	35.00	-15.80	M4	none
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	8.84	18.93	-1.47	17.46	35.00	-17.54	M4	none
	20	40620	4	16QAM	1	0	Acoustic	7.30	17.26	0.67	17.93	35.00	-17.07	M4	none
	20	40620	5	16QAM	1	0	Acoustic	5.81	15.29	3.63	18.92	35.00	-16.08	M4	none
	20	40620	6	16QAM	1	0	Acoustic	11.72	21.38	-2.53	18.85	35.00	-16.15	M4	none

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Table 10-3 LTE TDD B48 Power Class 3 UL-DL Configuration Results

					<u> </u>	10 1	01101 0	400 0 0	,	, or mgar	auon i	oouito			
Mode / Band	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	55773	0	16QAM	1	0	Acoustic	10.84	20.70	-3.28	17.42	35.00	-17.58	M4	none
	20	55773	1	16QAM	1	0	Acoustic	9.33	19.39	-1.58	17.81	35.00	-17.19	M4	none
	20	55773	2	16QAM	1	0	Acoustic	7.19	17.14	1.47	18.61	35.00	-16.39	M4	none
LTE TDD / Band 48	20	55773	3	16QAM	1	0	Acoustic	8.00	18.06	-1.50	16.56	35.00	-18.44	M4	none
	20	55773	4	16QAM	1	0	Acoustic	7.28	17.24	0.66	17.90	35.00	-17.10	M4	none
	20	55773	5	16QAM	1	0	Acoustic	5.40	14.64	3.61	18.25	35.00	-16.75	M4	none
	20	55773	6	16QAM	1	0	Acoustic	11.41	21.15	-2.51	18.64	35.00	-16.36	M4	none

III. Conclusion

Per the results above, UL-DL Configuration 2 was used for LTE TDD B41 Power Class 3 testing. UL-DL Configuration 6 was used for LTE TDD B48 Power Class 3 testing.

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OVERALL MEASUREMENT SUMMARY

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I. E-FIELD EMISSIONS:

Table 11-1 HAC Data Summary for CDMA E-field

				IIAO D	itu Ouiii	illaly io		- 1101G				
Mode	Channel	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons											
	1013	RC1/SO3	Acoustic	24.48	13.79	22.79	3.01	25.80	45.00	-19.20	M4	none
Cellular CDMA	384	RC1/SO3	Acoustic	24.51	11.80	21.44	3.04	24.48	45.00	-20.52	M4	none
	777	RC1/SO3	Acoustic	24.60	12.38	21.85	3.06	24.91	45.00	-20.09	M4	none
	25	RC1/SO3	Acoustic	23.92	8.80	18.89	3.02	21.91	35.00	-13.09	M4	none
PCS CDMA	600	RC1/SO3	Acoustic	24.04	9.26	19.33	3.05	22.38	35.00	-12.62	M4	none
	1175	RC1/SO3	Acoustic	23.93	7.46	17.45	3.08	20.53	35.00	-14.47	M4	none

Table 11-2 HAC Data Summary for GSM E-field

			• • • • • • • • • • • • • • • • • • • •	, 10 Data	Oullillia	., <u> </u>	CIVI E-IICI	<u> </u>			
Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons										
	128	Acoustic	32.47	30.37	29.65	3.50	33.15	45.00	-11.85	M4	none
GSM850	190	Acoustic	32.28	26.77	28.55	3.50	32.05	45.00	-12.95	M4	none
	251	Acoustic	32.45	31.99	30.10	3.50	33.60	45.00	-11.40	M4	none
	512	Acoustic	29.51	14.88	23.45	3.54	26.99	35.00	-8.01	M4	none
GSM1900	661	Acoustic	29.54	16.24	24.21	3.54	27.75	35.00	-7.25	M4	none
G3W1900	810	Acoustic	29.44	12.97	22.26	3.54	25.80	35.00	-9.20	M4	none
	661	T-Coil	29.54	17.37	24.80	3.54	28.34	35.00	-6.66	M4	none

Table 11-3 HAC Data Summary for LTF B41 (PC3) F-field

	TIAO Data Summary for LTL D41 (1 03) L-neid															
Mode / Band	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	-Field Emissions															
	15	39750	2	16QAM	1	0	Acoustic	23.07	8.61	18.70	1.39	20.09	35.00	-14.91	M4	none
	15	40185	2	16QAM	1	0	Acoustic	23.59	7.50	17.50	1.37	18.87	35.00	-16.13	M4	none
LTE TDD / Band 41 PC3	15	40620	2	16QAM	1	0	Acoustic	23.86	7.57	17.58	1.53	19.11	35.00	-15.89	M4	none
	15	41055	2	16QAM	1	0	Acoustic	23.50	7.12	17.05	1.48	18.53	35.00	-16.47	M4	none
	15	41490	2	16QAM	1	0	Acoustic	23.32	7.19	17.13	1.43	18.56	35.00	-16.44	M4	none

Table 11-4 HAC Data Summary for LTE B48 E-field

	nac data Summary for LTE 640 E-field															
Mode / Band	Bandwidth	Channel	UL-DL Config.		RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	E-Field Emissions															
	15	55315	6	64QAM	1	74	Acoustic	20.17	9.58	19.62	-2.41	17.21	35.00	-17.79	M4	none
LTE TDD /	15	55765	6	64QAM	1	74	Acoustic	20.80	10.22	20.19	-2.34	17.85	35.00	-17.15	M4	none
Band 48	15	56215	6	64QAM	1	74	Acoustic	20.66	9.13	19.21	-2.62	16.59	35.00	-18.41	M4	none
	15	56665	6	64QAM	1	74	Acoustic	20.50	10.09	20.08	-2.34	17.74	35.00	-17.26	M4	none

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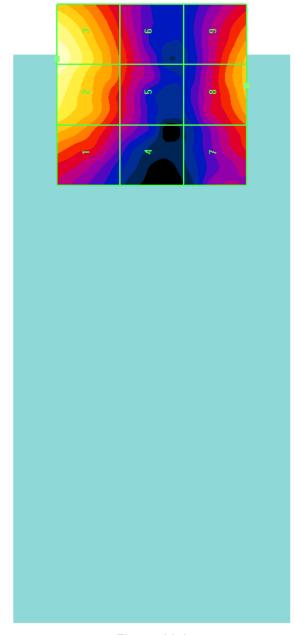


Figure 11-1
Sample E-field Scan Overlay
(T-Coil Centered scan area pictured. See Test Setup Photographs for actual WD overlay and Acoustic Centered scan area.)

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II. Worst-case Configuration Evaluation

Table 11-5 Peak Reading 360° Probe Rotation at Azimuth axis

	Teak Neading 300 Trobe Notation at Azimuth axis										
Mode	Channel	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5	
Probe Rotation	Probe Rotation at Worst-Case										
GSM1900	661	T-Coil	17.43	24.83	3.54	28.37	35.00	-6.63	M4	none	

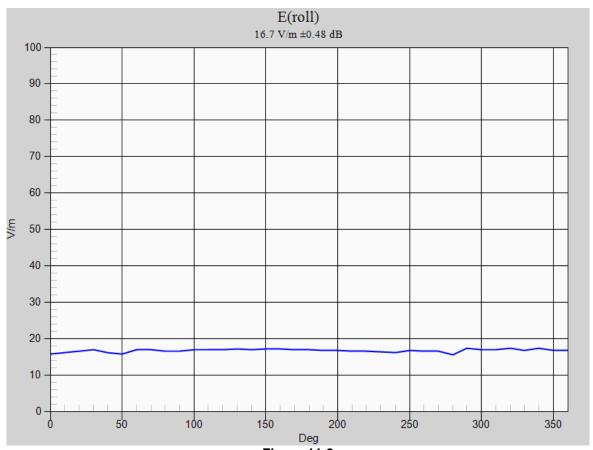


Figure 11-2 **Worst-Case Probe Rotation about Azimuth axis**

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^{*} Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

EQUIPMENT LIST 12.

Table 12-1 Equipment List

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E5515C	8960 Series 10 Wireless Communications Test Set	12/18/2018	Annual	12/18/2019	GB42230325
Agilent	E4438C	ESG Vector Signal Generator	4/19/2018	Annual	4/19/2019	MY47270002
Agilent	E4432B	ESG-D Series Signal Generator	4/19/2018	Annual	4/19/2019	US40053896
Agilent	N5182A	MXG Vector Signal Generator	11/28/2018	Annual	11/28/2019	MY47420603
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	ML2496A	Power Meter	10/21/2018	Annual	10/21/2019	1138001
Anritsu	MA2411B	Pulse Power Sensor	11/20/2018	Annual	11/20/2019	1339007
Anritsu	MA2411B	Pulse Power Sensor	11/20/2018	Annual	11/20/2019	1339008
Anritsu	MA24106A	USB Power Sensor	1/31/2019	Annual	1/31/2020	1520503
Anritsu	MA24106A	USB Power Sensor	1/31/2019	Annual	1/31/2020	1520501
Control Company	4040	Temperature / Humidity Monitor	2/28/2018	Biennial	2/28/2020	150761911
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMW500	Radio Communication Tester	4/20/2018	Annual	4/20/2019	128635
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	1/30/2019	Annual	1/30/2020	162125
Rohde & Schwarz	CMW500	Radio Communication tester	8/3/2018	Annual	8/3/2019	140144
Seekonk	NC-100	Torque Wrench (8" lb)	5/23/2018	Biennial	5/23/2020	N/A
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	DAE4	Dasy Data Acquisition Electronics	3/7/2018	Annual	3/7/2019	1415
SPEAG	CD2600V3	Freespace 2600 MHz Dipole	6/14/2017	Biennial	6/14/2019	1013
SPEAG	CD3500V3	Freespace 3500 MHz Dipole	1/15/2019	Biennial	1/15/2021	1005
SPEAG	CD835V3	Freespace 835 MHz Dipole	5/16/2018	Biennial	5/16/2020	1082
SPEAG	EF3DV3	Freespace E-field Probe	1/16/2019	Annual	1/16/2020	4035
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	5/16/2018	Biennial	5/16/2020	1064

Calibration traceable to the National Institute of Standards and Technology (NIST).

*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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13. MEASUREMENT UNCERTAINTY

Table 13-1 Uncertainty Estimation Table

	Uncertainty Estimation Table Wireless Communications Device Near-Field Measurement						
		Uncert	ainty Estima	ation			
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System	-	-	-			-	
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]					1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
 equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
 and NIST Tech Note 1297 and UKAS M3003.
- 2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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14. TEST DATA

See following Attached Pages for Test Data.

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DUT: CD835V3 - SN1082

Type: CD835V3 Serial: 1082

Communication System: CW; Frequency: 835 MHz;

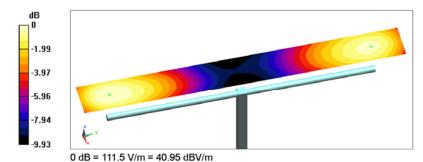
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 127.6 V/m; Power Drift = 0.03 dB Applied MIF = 0.00 dB Average value of Peak (interpolated) = 109.0 V/m



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DUT: CD1880V3 - SN1064

Type: CD1880V3 Serial: 1064

Communication System: CW; Frequency: 1880 MHz;

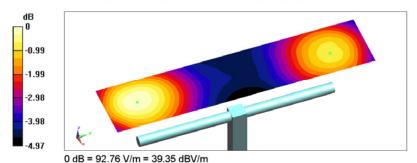
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 147.0 V/m; Power Drift = 0.07 dB Applied MIF = 0.00 dB Average value of Peak (interpolated) = 88.7 V/m



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DUT: CD2600V3 - SN1013

Type: CD2600V3 Serial: 1013

Communication System: CW; Frequency: 2600 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- . Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

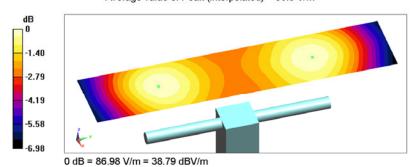
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 69.38 V/m; Power Drift = 0.07 dB

Applied MIF = 0.00 dB

Average value of Peak (interpolated) = 86.8 V/m



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DUT: CD3500V3 - SN1005

Type: CD3500V3 Serial: 1005

Communication System: CW; Frequency: 3500 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

3500 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

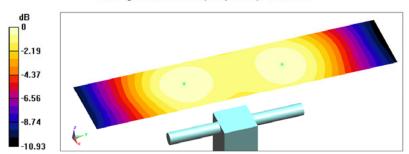
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 37.35 V/m; Power Drift = 0.08 dB

Applied MIF = 0.00 dB

Average value of Peak (interpolated) = 86.6 V/m



0 dB = 85.76 V/m = 38.67 dBV/m

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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:8

Communication System: CDMA; Frequency: 824.7 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

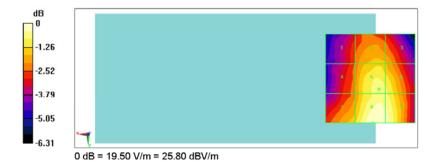
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

Cellular CDMA Low Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 17.43 V/m; Power Drift = -0.14 dB Applied MIF = 3.01 dB RF audio interference level = 25.80 dBV/m Emission category: M4

MIF scaled E-field

IIII COUICA E IIOIA				
Grid 1 M4	Grid 2 M4	Grid 3 M4		
23.34 dBV/m	24.38 dBV/m	24.17 dBV/m		
Grid 4 M4	Grid 5 M4	Grid 6 M4		
23.67 dBV/m	25.14 dBV/m	25.05 dBV/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4		
24.56 dBV/m	25.8 dBV/m	25.6 dBV/m		



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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:8

Communication System: CDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

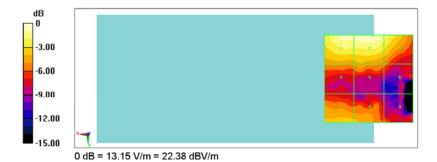
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

PCS CDMA Mid Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 5.181 V/m; Power Drift = -0.14 dB Applied MIF = 3.05 dB RF audio interference level = 22.38 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
21.94 dBV/m	22.38 dBV/m	21.1 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.77 dBV/m	18.21 dBV/m	16.99 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
19.09 dBV/m	18.93 dBV/m	16.9 dBV/m



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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

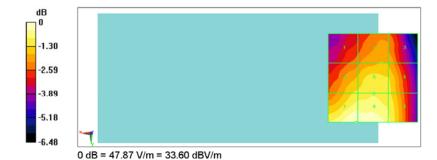
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

GSM850 High Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 40.66 V/m; Power Drift = 0.13 dB
Applied MIF = 3.50 dB
RF audio interference level = 33.60 dBV/m
Emission category: M4

MIF scaled E-field

min oddiod E no	IIII COUICA E IIOIA				
Grid 1 M4	Grid 2 M4	Grid 3 M4			
31.33 dBV/m	31.92 dBV/m	31.87 dBV/m			
Grid 4 M4	Grid 5 M4	Grid 6 M4			
32.5 dBV/m	32.67 dBV/m	32.46 dBV/m			
Grid 7 M4	Grid 8 M4	Grid 9 M4			
33.6 dBV/m	33.59 dBV/m	32.93 dBV/m			



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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

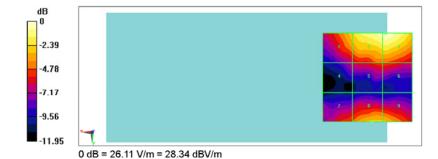
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

GSM1900 Mid Channel, T-Coil Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 7.705 V/m; Power Drift = 0.10 dB
Applied MIF = 3.54 dB
RF audio interference level = 28.34 dBV/m
Emission category: M4

MIF scaled E-field

min oddiod E noid					
Grid 1 M4	Grid 2 M4	Grid 3 M4			
25.73 dBV/m	28.23 dBV/m	28.34 dBV/m			
Grid 4 M4	Grid 5 M4	Grid 6 M4			
21.83 dBV/m	23.58 dBV/m	23.58 dBV/m			
Grid 7 M4	Grid 8 M4	Grid 9 M4			
23.54 dBV/m	25.49 dBV/m	25.45 dBV/m			



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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:4.67

Communication System: LTE TDD41; Frequency: 2506 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

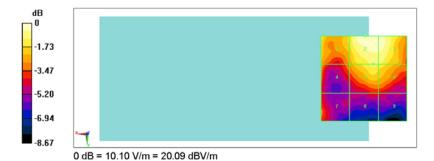
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

LTE TDD Band 41, 15MHz BW, Low Channel, UL-DL 2, 16QAM, 1RB, 0RB Offset, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 8.278 V/m; Power Drift = 0.10 dB
Applied MIF = 1.39 dB
RF audio interference level = 20.09 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
18.75 dBV/m	20.09 dBV/m	19.93 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.72 dBV/m	19.08 dBV/m	18.95 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
17.11 dBV/m	16.12 dBV/m	15.93 dBV/m



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Type: Portable Handset Serial: 1278B Backlight off Duty Cycle: 1:1.95

Communication System: LTE TDD Band 48; Frequency: 3602.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

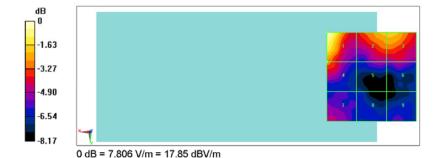
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1415; Calibrated: 3/7/2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

LTE TDD Band 48, 15MHz BW, Low-Mid Channel, UL-DL 6, 64QAM, 1RB, 74RB Offset, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 5.476 V/m; Power Drift = -0.17 dB Applied MIF = -2.34 dB RF audio interference level = 17.85 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
17.85 dBV/m	15.86 dBV/m	15.85 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
14.98 dBV/m	12.85 dBV/m	13.19 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
13.09 dBV/m	11.91 dBV/m	12.24 dBV/m



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CALIBRATION CERTIFICATES 15.

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Calibration Laboratory of Schmid & Partner

Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client

PC Test

Certificate No: EF3-4035_Jan19/2

CALIBRATION CERTIFICATE (Replacement of No: EF3-4035_Jan19)

Object

EF3DV3-SN:4035

Calibration procedure(s)

QA CAL-02.v9, QA CAL-25.v7

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

January 16, 2019

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: S5277 (20x)	04-Apr-18 (No. 217-02682)	Apr-19
DAE4	SN: 789	14-Jan-19 (No. DAE4-789_Jan19)	Jan-20
Reference Probe ER3DV6	SN: 2328	09-Oct-18 (No. ER3-2328_Oct18)	Oct-19
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-18)	In house check: Jun-20
Network Analyzer E8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19

	Name	Function	Signature	
Calibrated by:	Manu Seltz	Laboratory Technician	AN THE	
Approved by:	Katja Pokovic	Technical Manager	Alls	

Issued: February 11, 2019

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

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Glossary:

NORMx,y,z DCP

sensitivity in free space diode compression point

CF A, B, C, D crest factor (1/duty_cycle) of the RF signal

En Ep

modulation dependent linearization parameters incident E-field orientation normal to probe axis incident E-field orientation parallel to probe axis

Polarization φ

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.1.1, May 2017

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency_response$ (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	0.90	0.74	1.20	± 10.1 %
DCP (mV) ^B	96.8	98.5	95.3	

Calibration results for Frequency Response (30 MHz = 6 GHz)

Frequency MHz	Target E-Field V/m	Measured E-field (En) V/m	Deviation E-normal in %	Measured E-field (Ep) V/m	Deviation E-normal in %	Unc (k=2) %
30	77.3	76.8	-0.6%	77.3	0.1%	± 5.1 %
100	77.3	78.2	1.2%	77.8	0.7%	± 5.1 %
450	77.1	78.2	1.5%	77.8	0.9%	± 5.1 %
600	77.1	77.8	0.9%	77.5	0.5%	± 5.1 %
750	77.3	77.7	0.5%	77.2	-0.1%	± 5.1 %
1800	140.3	136.9	-2.4%	137.2	-2.2%	± 5.1 %
2000	133.0	129.4	-2.8%	129.4	-2.7%	± 5.1 %
2200	124.8	121.5	-2.7%	122.7	-1.7%	± 5.1 %
2500	123.7	120.7	-2.4%	121.9	-1.5%	± 5.1 %
3000	78.8	74.8	-5.0%	76.1	-3.5%	± 5.1 %
3500	256.3	248.1	-3.2%	246.0	-4.0%	± 5.1 %
3700	249.7	239.2	-4.2%	239.0	-4.3%	± 5.1 %
5200	50.7	50.7	-0.1%	51.2	0.9%	± 5.1 %
5500	49.6	48.9	-1.5%	48.7	-1.9%	± 5.1 %
5800	48.9	49.1	0.4%	49.3	0.8%	± 5.1 %

Calibration Results for Modulation Response

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Max dev.	Unc [±] (k=2)
0	CW	X	0.0	0.0	1.0	0.00	141.5	+ 3.3 %	± 4.7 %
		Υ	0.0	0.0	1.0		125.6	,,,,,,,	
		Υ	0.0	0.0	1.0		125.1		

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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⁸ Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

EF3DV3 - SN:4035 January 16, 2019

DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Sensor Frequency Model Parameters

	Sensor X	Sensor Y	Sensor Z
Frequency Corr. (LF)	0.28	0.21	5.68
Frequency Corr. (HF)	2.82	2.82	2.82

Other Probe Parameters

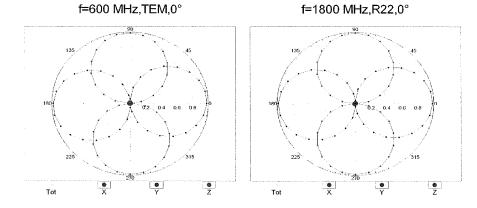
Sensor Arrangement	Rectangular
Connector Angle (°)	57.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	1.5 mm
Probe Tip to Sensor Y Calibration Point	1.5 mm
Probe Tip to Sensor Z Calibration Point	1.5 mm

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FCC ID: A3LSMG977U	TREINCESTIBLE CARDEATORY, INC.	C (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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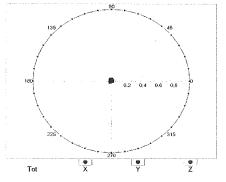
EF3DV3 - SN:4035 January 16, 2019

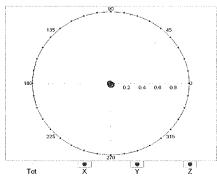
Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

f=600 MHz,TEM,90° f=1800 MHz,R22,90°



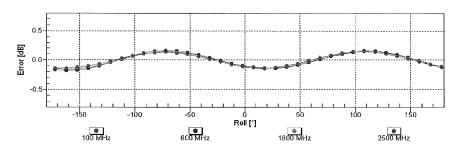


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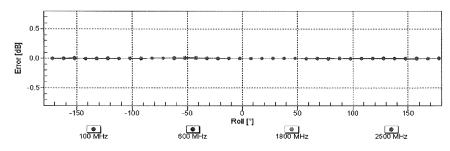
EF3DV3 – SN:4035 January 16, 2019

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

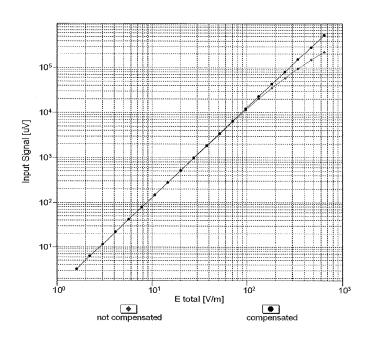
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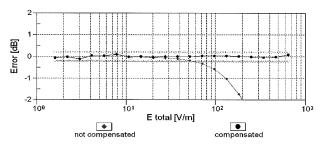
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EF3DV3 - SN:4035 January 16, 2019

Dynamic Range f(E-field) (TEM cell, f = 900 MHz)





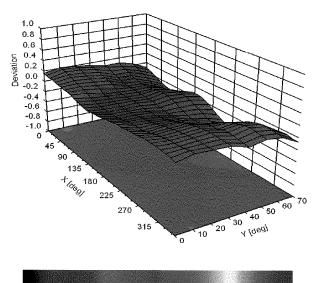
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

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EF3DV3 - SN:4035 January 16, 2019

Deviation from Isotropy in Air Error (ϕ , ϑ), f = 900 MHz



-0.6

Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ (k=2)

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Accreditation No.: SCS 0108

Client PC Tes

Certificate No: CD835V3-1082_May18

Object	CD835V3 - SN:	1082	
Calibration procedure(s)	QA CAL-20.v6 Calibration proce	edure for dipoles in air	104 6/5/2018
Calibration date:	May 16, 2018		
The measurements and the unce	ertainties with confidence p	onal standards, which realize the physical uni robability are given on the following pages an ry facility: environment temperature (22 ± 3)°C	d are part of the certificate.
Calibration Equipment used (M&	TE critical for calibration)		
Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02683)	Apr-19
Probe EF3DV3	SN: 4013	05-Mar-18 (No. EF3-4013_Mar18)	Mar-19
DAE4	SN: 781	17-Jan-18 (No. DAE4-781_Jan18)	Jan-19
Secondary Standards	ID#	Check Date (in house)	Scheduled Check
	SN: GB42420191	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
Power meter Agilent 4419B		09-Oct-09 (in house check Oct-17)	In house check: Oct-20
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: US37295597		In house check: Oct-20
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	III House check. Oct-20
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06		27-Aug-12 (in house check Oct-17) 18-Oct-01 (in house check Oct-17)	In house check: Oct-18
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8753E	SN: 832283/011		
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8753E	SN: 832283/011 SN: US37390585	18-Oct-01 (in house check Oct-17)	In house check: Oct-18
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 832283/011 SN: US37390585 Name	18-Oct-01 (in house check Oct-17) Function	In house check: Oct-18 Signature

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FCC ID: A3LSMG977U	PETEST - LINE LANDIA FORF, INC.	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





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References

 ANSI-C63.19-2011
 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any electrodes.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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 Approved by: Quality Manager

 Filename:
 Test Dates:
 DUT Type:

 1M1901100003-20-R2.A3L
 02/25/2019 - 02/28/2019
 Portable Handset

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.1
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	112.4 V/m = 41.02 dBV/m
Maximum measured above low end	100 mW input power	109.3 V/m = 40.77 dBV/m
Averaged maximum above arm	100 mW input power	110.9 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.6 dB	40.9 Ω - 10.0 jΩ
835 MHz	26.9 dB	53.5 Ω + 3.2 jΩ
880 MHz	16.8 dB	61.9 Ω - 11.1 jΩ
900 MHz	16.1 dB	52.4 Ω - 16.1 jΩ
945 MHz	22.1 dB	43.6 Ω + 3.8 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

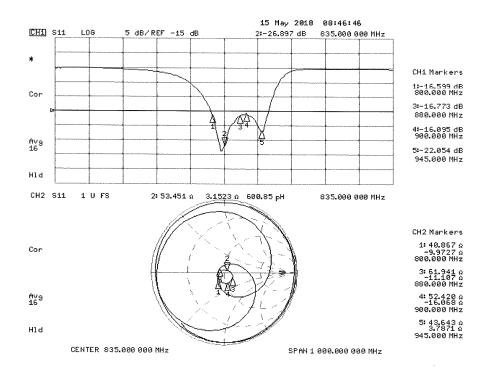
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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Impedance Measurement Plot



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DASY5 E-field Result

Date: 16.05.2018

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1082

Communication System: UID 0 - CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 835 MHz; Calibrated: 05.03.2018;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 17.01.2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.1(1476); SEMCAD X 14.6.11(7439)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 131.4 V/m; Power Drift = 0.00 dB

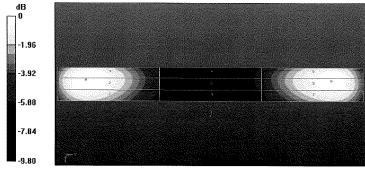
Applied MIF = 0.00 dB

RF audio interference level = 41.02 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M3 40.48 dBV/m		Grid 3 M3 40.99 dBV/m
Grid 4 M4 35.64 dBV/m	Grid 5 M4 36.09 dBV/m	
Grid 7 M3 40.38 dBV/m		Grid 9 M3 40.73 dBV/m



0 dB = 112.4 V/m = 41.02 dBV/m

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Accreditation No.: SCS 0108

Client

Certificate No: CD1880V3-1064 May18

CALIBRATION CERTIFICATE Object CD1880V3 - SN: 1064 QA CAL-20.v6 Calibration procedure(s) Calibration procedure for dipoles in air Calibration date: May 16, 2018 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature $(22 \pm 3)^{\circ}$ C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards ID# Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 04-Apr-18 (No. 217-02672/02673) Apr-19 Power sensor NRP-Z91 SN: 103244 04-Apr-18 (No. 217-02672) Apr-19 Power sensor NRP-Z91 SN: 103245 04-Apr-18 (No. 217-02673) Apr-19 Reference 20 dB Attenuator SN: 5058 (20k) 04-Apr-18 (No. 217-02682) Apr-19 Type-N mismatch combination SN: 5047.2 / 06327 04-Apr-18 (No. 217-02683) Apr-19 Probe EF3DV3 SN: 4013 05-Mar-18 (No. EF3-4013_Mar18) Mar-19 DAE4 SN: 781 17-Jan-18 (No. DAE4-781 Jan18) Jan-19 Secondary Standards Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-17) In house check: Oct-20 Power sensor HP E4412A SN: US38485102 05-Jan-10 (in house check Oct-17) In house check: Oct-20 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-17) In house check: Oct-20 RF generator R&S SMT-06 SN: 832283/011 27-Aug-12 (in house check Oct-17) In house check: Oct-20 Network Analyzer HP 8753E SN: US37390585 18-Oct-01 (in house check Oct-17) In house check: Oct-18 Name Function Calibrated by: Leif Klysner Laboratory Technician Approved by: Katja Pokovic Technical Manager Issued: May 18, 2018 This calibration certificate shall not be reproduced except in full without written approval of the laboratory

Certificate No: CD1880V3-1064_May18 Page 1 of 5

FCC ID: A3LSMG977U	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 99 of 119
1M1901100003-20-R2.A3L	02/25/2019 - 02/28/2019	Portable Handset		rage 99 01 119

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

References

1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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FCC ID: A3LSMG977U

HAC (RF EMISSIONS) TEST REPORT

Quality Manager

Filename:

DUT Type:

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Portable Handset

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02/25/2019 - 02/28/2019

1M1901100003-20-R2.A3L

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.1
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	90.1 V/m = 39.09 dBV/m
Maximum measured above low end	100 mW input power	87.8 V/m = 38.87 dBV/m
Averaged maximum above arm	100 mW input power	89.0 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
1730 MHz	25.9 dB	52.9 Ω + 4.3 jΩ
1880 MHz	20.5 dB	57.7 Ω + 6.7 jΩ
1900 MHz	20.7 dB	$59.3 \Omega + 3.8 j\Omega$
1950 MHz	27.1 dB	53.8 Ω - 2.5 jΩ
2000 MHz	23.1 dB	46.5 Ω + 5.8 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

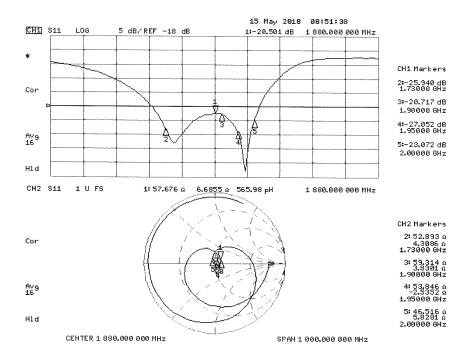
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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FCC ID: A3LSMG977U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Impedance Measurement Plot



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Filename:	Test Dates:	DUT Type:		Page 102 of 119
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DASY5 E-field Result

Date: 16.05.2018

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1064

Communication System: UID 0 - CW ; Frequency: 1880 MHz Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 1880 MHz; Calibrated: 05.03.2018;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 17.01.2018
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.1(1476); SEMCAD X 14.6.11(7439)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 153.6 V/m; Power Drift = -0.00 dB

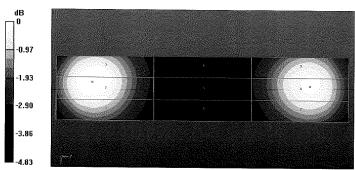
Applied MIF = 0.00 dB

RF audio interference level = 39.09 dBV/m

Emission category: M2

MIF scaled E-field

	1	Grid 3 M2
38.62 dBV/m	39.09 dBV/m	39.07 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
35.96 dBV/m	36.16 dBV/m	36.14 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.54 dBV/m	38.87 dBV/m	38.81 dBV/m



0 dB = 90.09 V/m = 39.09 dBV/m

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FCC ID: A3LSMG977U	INCIDENT HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Client PC Test

Certificate No: CD2600V3-1013_Jun17/2

CALIBRATION CERTIFICATE (Replacement of No:CD2600V3-1013_Jun17)

Object CD2600V3 - SN: 1013

Calibration procedure(s) QA CAL-20.v6

Calibration procedure for dipoles in air

08/02/201

Calibration date:

June 14, 2017

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).

The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 \pm 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-17 (No. 217-02521/02522)	Apr-18
Power sensor NRP-Z91	SN: 103244	04-Apr-17 (No. 217-02521)	Apr-18
Power sensor NRP-Z91	SN: 103245	04-Apr-17 (No. 217-02522)	Apr-18
Reference 20 dB Attenuator	SN: 5058 (20k)	07-Apr-17 (No. 217-02528)	Apr-18
Type-N mismatch combination	SN: 5047.2 / 06327	07-Apr-17 (No. 217-02529)	Apr-18
Probe EF3DV6	SN: 4013	21-Jun-16 (No. EF3-4013_Jun16)	Jun-17
DAE4	SN: 781	02-Sep-16 (No. DAE4-781_Sep16)	Sep-17
Secondary Standards	ID#	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Sep-14)	In house check: Oct-17
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Sep-14)	In house check: Oct-17
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Sep-14)	In house check: Oct-17
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-15)	In house check: Oct-17
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Oct-16)	In house check: Oct-17
	Name	Function	Signature
Calibrated by:	Johannes Kurikka	Laboratory Technician	rue-14-
Approved by:	Kalja Pokovic	Technical Manager	RA

Issued: July 20, 2017

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD2600V3-1013_Jun17/2

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FCC ID: A3LSMG977U	PETEST HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network
 Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was
 eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
 obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is	stated as the sta	ndard uncertainty	of measureme	ent multiplied by the
coverage factor k=2, which for a normal distri				

		 	
Certificate No: CD2600V3-1013_Jun17/2	Page 2 of 5		

FCC ID: A3LSMG977U	PETEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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Measurement Conditions

DASY system configuration, as far as not given on page 1

DASY Version	DASY5	V52.10.0
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	· · · · · · · · · · · · · · · · · · ·

Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	84.9 V/m = 38.58 dBV/m
Maximum measured above low end	100 mW input power	84.0 V/m = 38.48 dBV/m
Averaged maximum above arm	100 mW input power	84.5 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
2450 MHz	23.3 dB	44.8 Ω - 3.8 jΩ
2550 MHz	32.2 dB	$51.0 \Omega + 2.3 j\Omega$
2600 MHz	29.5 dB	53.4 Ω - 0.3 jΩ
2650 MHz	27.0 dB	53.2 Ω - 3.3 jΩ
2750 MHz	19.7 dB	45.7 Ω - 8.9 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

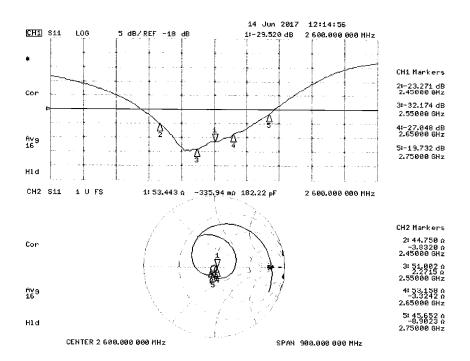
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD2600V3-1013_Jun17/2

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FCC ID: A3LSMG977U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager	
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Impedance Measurement Plot



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FCC ID: A3LSMG977U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 107 of 110
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DASY5 E-field Result

Date: 14.06.2017

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1013

Communication System: UID 0 - CW; Frequency: 2600 MHz Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1); Calibrated:21.06.2016;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 02.09.2016
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.0(1444); SEMCAD X 14.6.10(7416)

Dipole E-Field measurement @ 2600MHz - with EF_4013/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 68.41 V/m; Power Drift = -0.01 dB

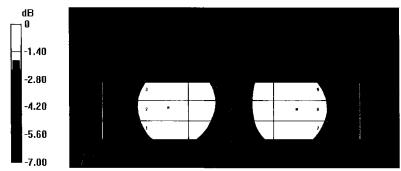
PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 84.92 V/m

Near-field category: M3 (AWF 0 dB)

PMF scaled E-field

Grid 1 M3 81.71 V/m	
Grid 4 M3 77.39 V/m	
Grid 7 M3 82.82 V/m	



0 dB = 84.92 V/m = 38.58 dBV/m

Certificate No: CD2600V3-1013_Jun17/2

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FCC ID: A3LSMG977U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
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Calibration Laboratory of Schmid & Partner Engineering AG

Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

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Client

PC Tes

Certificate No: CD3500V3-1005_Jan19

Object	CD3500V3 - SN: 1005				
Calibration procedure(s)	QA CAL-20.v7 Calibration Procedure for Validation Sources in air 2 \(\sqrt{20}^{9}\)				
Calibration date:	January 15, 201	9			
The measurements and the unce	ertainties with confidence p	ional standards, which realize the physical units probability are given on the following pages and ry facility: environment temperature $(22 \pm 3)^{\circ}$ C	are part of the certificate.		
Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration		
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19		
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19		
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19		
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19		
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682)			
Probe EF3DV3	SN: 4013	03-Jan-19 (No. EF3-4013 Jan19)	Apr-19		
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20 Jan-20		
Secondary Standards	' ID #	Check Date (in house)	Scheduled Check		
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-17)	In house check: Oct-20		
	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20		
Power sensor HP E4412A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20		
Power sensor HP E4412A Power sensor HP 8482A		27-Aug-12 (in house check Oct-17)	In house check: Oct-20		
ower sensor HP 8482A	SN: 832283/011		1.1. 1.1.0.140		
	SN: 832283/011 SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19		
Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	SN: US41080477	Function	Signature		
Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	SN: US41080477	,			
Power sensor HP 8482A RF generator R&S SMT-06	SN: US41080477	Function			

Certificate No: CD3500V3-1005_Jan19 Page 1 of 5

FCC ID: A3LSMG977U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.					
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Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	3500 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 3500 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	85.1 V/m = 38.60 dBV/m
Maximum measured above low end	100 mW input power	83.1 V/m = 38.39 dBV/m
Averaged maximum above arm	100 mW input power	84.1 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
3300 MHz	22.2 dB	58.1 Ω + 2.1 jΩ
3400 MHz	29.7 dB	53.4 Ω - 0.3 jΩ
3500 MHz	25.4 dB	55.2 Ω - 2.4 jΩ
3600 MHz	22.1 dB	49.6 Ω - 7.8 jΩ
3700 MHz	19.7 dB	41.3 Ω - 3.6 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

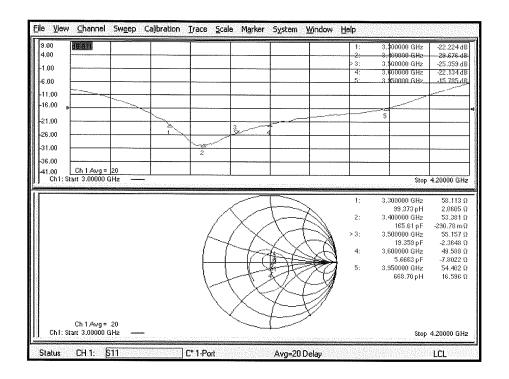
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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Impedance Measurement Plot



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DASY5 E-field Result

Date: 15.01.2019

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 3500 MHz; Type: CD3500V3; Serial: CD3500V3 - SN: 1005

Communication System: UID 0 - CW; Frequency: 3500 MHz Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 3500 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

$\textbf{Dipole E-Field measurement @ 3500MHz/E-Scan - 3500MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): } \\ \textbf{Interpolated grid: } dx=0.5000 \text{ mm, } dy=0.5000 \text{ mm}, \\ \textbf{dy=0.5000 mm, } dy=0.5000 \text{ mm}, \\ \textbf{dy=0.5000 mm, } dy=0.5000 \text{ mm}, \\ \textbf{dy=0.5000 mm, } dy=0.5000 \text{ mm}, \\ \textbf{dy=0.5000 mm, } dy=0.5000 \text{ mm}, \\ \textbf{dy=0.5000 mm}, \\ \textbf{dy=0.50$

Device Reference Point: 0, 0, -6.3 mm Reference Value = 34.54 V/m; Power Drift = 0.02 dB

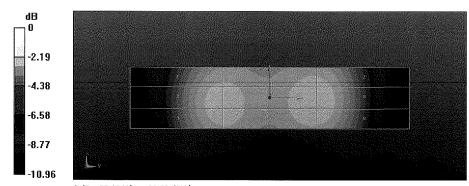
Applied MIF = 0.00 dB

RF audio interference level = 38.60 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
38.08 dBV/m	38.39 dBV/m	38.38 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
38.36 dBV/m	38.6 dBV/m	38.55 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.35 dBV/m	38.60 dBV/m	38.54 dBV/m



0 dB = 85.13 V/m = 38.60 dBV/m

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CONCLUSION 16.

The measurements taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017, indicate that the wireless communications device complies with the HAC limits specified in ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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17. REFERENCES

- 1. ANSI/IEEE C63.19-2011, "American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.", New York, NY, IEEE, May 2011
- 2. CTIA Certification Program, "Test Plan for Hearing Aid Compatibility Rev 3.1.1", Washington, DC, CTIA, May 2017
- 3. FCC Office of Engineering and Technology KDB, "285076 D01 HAC Guidance v05," September 13, 2017
- 4. FCC Office of Engineering and Technology KDB, "285076 D02 T-Coil Testing for CMRS IP v03," September 13, 2017
- 5. FCC Public Notice DA 06-1215, Wireless Telecommunications Bureau and Office of Engineering and Technology Clarify Use of Revised Wireless Phone Hearing Aid Compatibility Standard, June 6, 2006
- 6. FCC 3G Review Guidance, Laboratory Division OET FCC, May/June 2006
- 7. Berger, H. S., "Compatibility Between Hearing Aids and Wireless Devices," Electronic Industries Forum, Boston, MA, May, 1997
- 8. Berger, H. S., "Hearing Aid and Cellular Phone Compatibility: Working Toward Solutions," Wireless Telephones and Hearing Aids: New Challenges for Audiology, Gallaudet University, Washington, D.C., May, 1997 (To be reprinted in the American Journal of Audiology).
- 9. Berger, H. S., "Hearing Aid Compatibility with Wireless Communications Devices, " IEEE International Symposium on Electromagnetic Compatibility, Austin, TX, August, 1997.
- 10. Bronaugh, E. L., "Simplifying EMI Immunity (Susceptibility) Tests in TEM Cells," in the 1990 IEEE International Symposium on Electromagnetic Compatibility Symposium Record, Washington, D.C., August 1990, pp. 488-491
- 11. Byme, D. and Dillon, H., The National Acoustics Laboratory (NAL) New Procedure for Selecting the Gain and Frequency Response of a Hearing Aid, Ear and Hearing 7:257-265, 1986.
- 12. Crawford, M. L., "Measurement of Electromagnetic Radiation from Electronic Equipment using TEM Transmission Cells, "U.S. Department of Commerce, National Bureau of Standards, NBSIR 73-306, Feb. 1973.
- 13. Crawford, M. L., and Workman, J. L., "Using a TEM Cell for EMC Measurements of Electronic Equipment," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1013, July 1981.
- 14. Decker, W. F., Crawford, M. L., and Wilson, W. A., "Construction of a Large Transverse Electromagnetic Cell", U.S. Department of Commerce, National Bureau of Standards, Technical Note 1011, Feb. 1979.
- 15. EHIMA GSM Project, Development phase, Project Report (1st part) Revision A. Technical-Audiological Laboratory and Telecom Denmark, October 1993.

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- 16. EHIMA GSM Project, Development phase, Part II Project Report. Technical-Audiological Laboratory and Telecom Denmark, June 1994.
- 17. EHIMA GSM Project Final Report, Hearing Aids and GSM Mobile Telephones: Interference Problems, Methods of Measurement and Levels of Immunity. Technical-Audiological Laboratory and Telecom Denmark. 1995.
- 18. HAMPIS Report, Comparison of Mobile phone electromagnetic near field with an upscaled electromagnetic far field, using hearing aid as reference, 21 October 1999.
- 19. Hearing Aids/GSM, Report from OTWIDAM, Technical-Audiological Laboratory and Telecom Denmark, April 1993.
- 20. IEEE 100, The Authoritative Dictionary of IEEE Standards Terms, Seventh Edition.
- 21. Joyner, K. H., et. al., Interference to Hearing Aids by the New Digital Mobile Telephone System, Global System for Mobile (GSM) Communication Standard, National Acoustic Laboratory, Australian Hearing Series, Sydney 1993.
- 22. Joyner, K. H., et. al., Interference to Hearing Aids by the Digital Mobile Telephone System, Global System for Mobile Communications (GSM), NAL Report #131, National Acoustic Laboratory, Australian Hearing Series, Sydney, 1995.
- 23. Konigstein, D., and Hansen, D., "A New Family of TEM Cells with enlarged bandwidth and Optimized working Volume," in the Proceedings of the 7th International Symposium on EMC, Zurich, Switzerland, March 1987; 50:9, pp. 127-132.
- 24. Kuk, F., and Hjorstgaard, N. K., "Factors affecting interference from digital cellular telephones," Hearing Journal, 1997; 50:9, pp 32-34.
- 25. Ma, M. A., and Kanda, M., "Electromagnetic Compatibility and Interference Metrology," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1099, July 1986, pp. 17-43.
- 26. Ma, M. A., Sreenivashiah, I., and Chang, D. C., "A Method of Determining the Emission and Susceptibility Levels of Electrically Small Objects Using a TEM Cell." U.S. Department of Commerce, National Bureau of Standards, Technial Note 1040, July 1981.
- 27. McCandless, G. A., and Lyregaard, P. E., Prescription of Gain/Output (POGO) for Hearing Aids, Hearing Instruments 1:16-21, 1983
- 28. Skopec, M., "Hearing Aid Electromagnetic Interference from Digital Wireless Telephones, "IEEE Transactions on Rehabilitation Engineering, vol. 6, no. 2, pp. 235-239, June 1998.
- 29. Technical Report, GSM 05.90, GSM EMC Considerations, European Telecommunications Standards Institute, January 1993.
- 30. Victorian, T. A., "Digital Cellular Telephone Interference and Hearing Aid Compatibility—an Update," Hearing Journal 1998; 51:10, pp. 53-60
- 31. Wong, G. S. K., and Embleton, T. F. W., eds., AIP Handbook of Condenser Microphones: Theory, Calibration and Measurements, AIP Press.

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